

## 6 x 220mA LED Backlight Driver with Boost Controller

**MAX25560**

### General Description

The MAX25560 is a six-channel LED backlight driver with an integrated current-mode boost controller that operates over a switching frequency range of 400kHz to 2.2MHz and incorporates spread spectrum. Selectable phase-shifting of the output channels is included to reduce EMI. The MAX25560 provides up to 220mA per channel. The device is capable of operating down to very low battery voltages by virtue of a unique input voltage switching scheme.

Extensive diagnostics and an I<sup>2</sup>C interface are included in the device.

The MAX25560 is available in a compact TQFN package and operates over the -40°C to +125°C temperature range.

### Applications

- Automotive Instrument Clusters
- Automotive Central Information Displays
- Automotive Head-Up Displays

### Benefits and Features

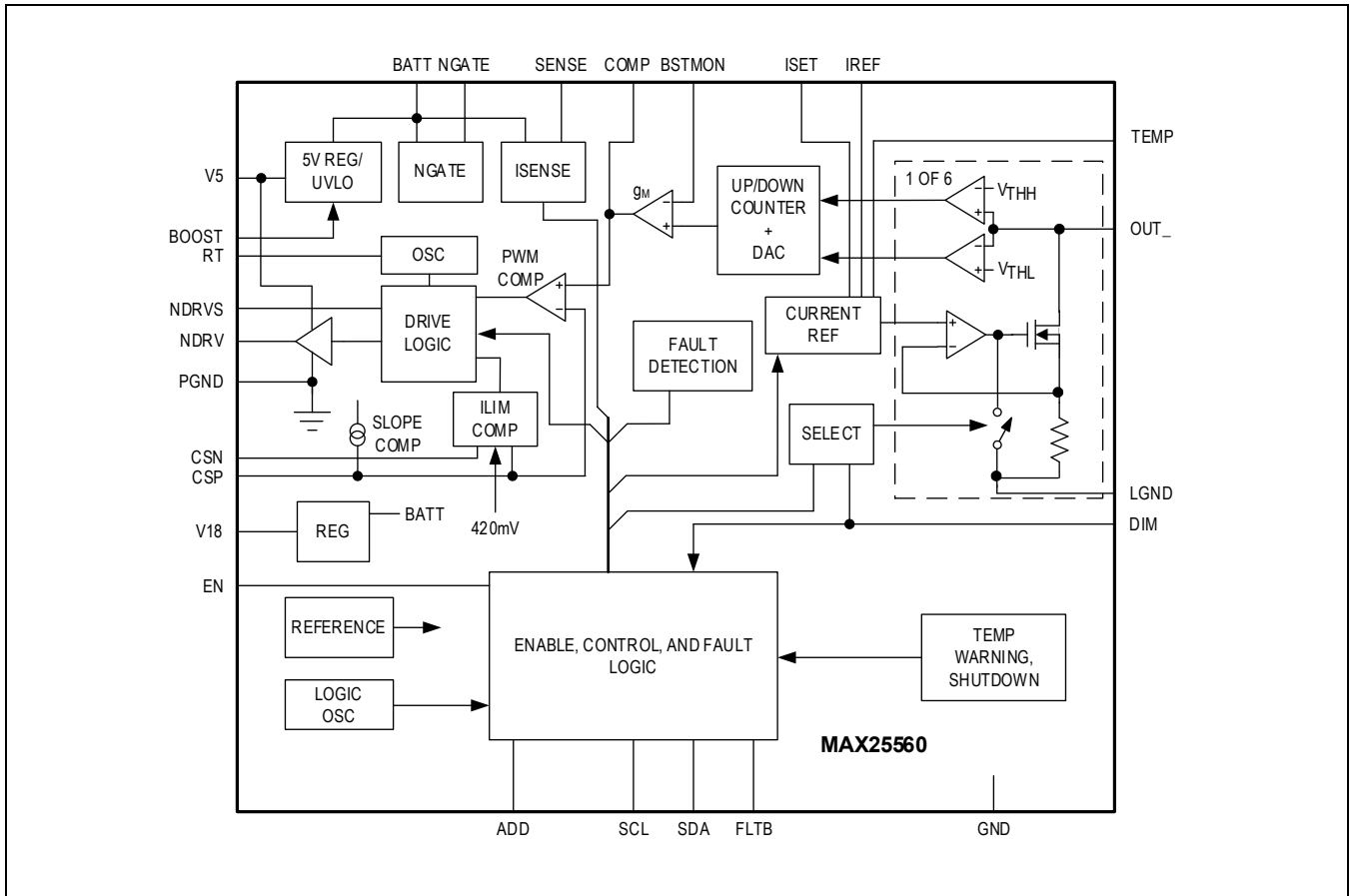
- Operates down to 3V on Battery Input while Maintaining 5V Gate Drive
  - Wide Boost Duty-Cycle Range
- Boost or SEPIC Current-Mode DC-DC Controller
  - 400kHz to 2.2MHz Operating Frequency Range
  - Optional Spread Spectrum
  - Can Be Synchronized to an External Clock
- LED Current Sinks
  - Up to 220mA Output Current per String
  - Low OUT\_ Regulation Voltage
  - Optional Phase-Shifting Between Channels
- 16667:1 Dimming Ratio at 200Hz
- External or Internal (I<sup>2</sup>C) Dimming
- >16667:1 Dimming Ratio with Hybrid Dimming
- Integrated Charge Pump to Drive Series nMOSFET
- Temperature Foldback Using External NTC Temperature Sensor
- Fast Startup Option without I<sup>2</sup>C Intervention Using EN Pin Only
- FLTB Output Provides Diagnostic Information
  - Shorted or Open LEDs
  - Any OUT\_ Pin Shorted to GND
  - IREF/RT Resistor out of Range
  - Thermal Warning/Shutdown
  - Undervoltage/Overvoltage on Boost Output
  - V18 Internal Supply out-of-Range
  - Input Overcurrent (Measured at Boost Input Using External Sense Resistor)
- I<sup>2</sup>C Interface
- Compact TQFN Package

[Ordering Information](#) appears at end of data sheet.

# 6 x 220mA LED Backlight Driver with Boost Controller

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## Simplified Block Diagram



## Absolute Maximum Ratings

|   |                     |
|---|---------------------|
| BATT, BOOST, OUT1-6, BSTMON, EN to GND      | -0.3V to +42V       |
| SENSE to BATT                               | 0.3V                |
| FLTB, DIM, SDA, SCL to GND                  | -0.3V to +6V        |
| PGND to GND                                 | -0.3V to +0.3V      |
| LGND1, 2 to GND                             | -0.3V to +0.3V      |
| NGATE to GND                                | -0.3V to +42V       |
| NGATE to BATT                               | 6V                  |
| V18 to GND                                  | -0.3V to +2.2V      |
| TEMP, CSP, COMP, IREF, ISET, RT, ADD to GND | -0.3V to V18 + 0.3V |
| V5 to GND                                   | -0.3V to +6V        |
| NDRV, NDRVS to GND                          | -0.3V to V5 + 0.3V  |

|   |                 |
|---|-----------------|
| NDRV Peak Current (<100ns)  | 3A              |
| NDRV Continuous Current   | 100mA           |
| OUT_ Continuous Current   | 250mA           |
| Continuous Power Dissipation (Single Layer Board) (T <sub>A</sub> = +70°C, derate 21.28mW/°C above +70°C) | 1702mW          |
| Continuous Power Dissipation (Multilayer Board) (T <sub>A</sub> = +70°C, derate 27.8mW/°C above +70°C)    | 2222mW          |
| Operating Temperature Range   | -40°C to +125°C |
| Junction Temperature Range  | -40°C to +150°C |
| Storage Temperature Range   | -65°C to +150°C |
| Lead Temperature (soldering, 10s)   | +300°C          |

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## Package Information

| Package Code                                 | T3255+6C                |
|--|-------------------------|
| Outline Number                               | <a href="#">21-0140</a> |
| Land Pattern Number                          | <a href="#">90-0603</a> |
| <b>Thermal Resistance, Four-Layer Board:</b> |                         |
| Junction to Ambient (θ <sub>JA</sub> )       | 36°C/W                  |
| Junction to Case (θ <sub>JC</sub> )          | 3°C/W                   |

## Electrical Characteristics

(Limits are 100% tested at T<sub>A</sub> = +25°C and T<sub>A</sub> = +125°C. Limits over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization. Specifications marked "GBD" are guaranteed by design and not production tested.)

| PARAMETER  | SYMBOL                | CONDITIONS             | MIN  | TYP  | MAX  | UNITS |
|--|-----------------------|------------------------|------|------|------|-------|
| <b>POWER SUPPLY</b>                                    |                       |                        |      |      |      |       |
| BATT Operating Voltage Range                           | V <sub>BATT</sub>     |                        | 4.5  |      | 36   | V     |
| BATT Operating Voltage Range after Startup             |                       | Maximum duration 100ms | 3    |      | 36   | V     |
| BATT Quiescent Supply Current                          | I <sub>BATT</sub>     | No switching           |      | 2.3  | 3    | mA    |
| BATT Shutdown Supply Current                           |                       |                        |      | 4    | 10   | μA    |
| BATT Undervoltage Lockout Rising                       |                       |                        | 4.1  | 4.25 | 4.35 | V     |
| BATT Undervoltage Lockout Falling                      |                       |                        | 2.77 | 2.9  | 2.95 | V     |
| BATT Threshold for Low-Voltage Operation Mode, Falling | V <sub>BATT_LVF</sub> |                        | 5.28 | 5.45 | 5.6  | V     |
| BATT Threshold for Low-Voltage Operation Mode, Rising  | V <sub>BATT_LVR</sub> |                        | 5.5  | 5.66 | 5.82 | V     |

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| PARAMETER                                  | SYMBOL               | CONDITIONS  | MIN  | TYP  | MAX  | UNITS         |
|--|----------------------|---|------|------|------|---------------|
| <b>V18 REGULATOR</b>                       |                      |   |      |      |      |               |
| V18 Output Voltage                         | $V_{V18\_ACC}$       | No load on V18  | 1.72 | 1.8  | 1.88 | V             |
| V18 Current Limit                          | $I_{LIM\_V18}$       | $V_{V18} = 1\text{V}$   | 50   |      |      | mA            |
| V18 Undervoltage Lockout                   | $V_{V18\_UVLO}$      | V18 voltage rising  | 1.6  | 1.65 | 1.7  | V             |
| V18 Undervoltage Hysteresis                | $V_{V18\_UVLO\_HYS}$ |   |      | 150  |      | mV            |
| V18 Power-on-Reset Level                   |                      | Design guidance   |      | 1.4  |      | V             |
| V18OOR Diagnostic Levels                   |                      |   | -8   |      | +8   | %             |
| <b>V5 REGULATOR</b>                        |                      |   |      |      |      |               |
| V5 Output Voltage                          | $V_{V5}$             | $V_{BATT} = 5.75\text{V to }36\text{V}$ , $I_{V5} = 10\text{mA}$  | 4.8  | 5    | 5.2  | V             |
| V5 Dropout Voltage                         | $V_{V5\_DRP}$        | $V_{BOOST} = 4.9\text{V}$ , $I_{V5} = 5\text{mA}$   |      | 0.18 | 0.3  | V             |
| V5 Undervoltage Lockout                    | $V_{V5\_UVLOR}$      | V5 voltage rising   | 3.75 | 3.9  | 4.05 | V             |
|  | $V_{V5\_UVLOF}$      | V5 voltage falling  | 3.6  | 3.7  | 3.8  |               |
| V5 Short-Circuit Current Limit             | $I_{V5\_SC}$         | V5 shorted to GND   | 30   |      |      | mA            |
| V5 Overvoltage Threshold, Rising           |                      |   | 5.6  | 5.75 | 5.85 | V             |
| V5 Overvoltage Threshold Hysteresis        |                      |   |      | 100  |      | mV            |
| <b>NGATE OUTPUT/INPUT CURRENT SENSING</b>  |                      |   |      |      |      |               |
| NGATE Output Voltage                       | $V_{NGATE}$          | Above $V_{BATT}$ , $3\text{V} < V_{BATT} < 33\text{V}$ , $I_{NGATE} = 1\mu\text{A}$                                   | 4.3  | 5.25 | 6.3  | V             |
| NGATE Source Current                       | $I_{NG\_SO}$         | $V_{NGATE} = V_{BATT}$  | 30   | 50   |      | $\mu\text{A}$ |
| NGATE Sink Current                         | $I_{NG\_SINK}$       | $V_{NGATE} = 14\text{V} = V_{BATT}$   | 6    | 10   |      | mA            |
| NGATE Output Voltage at High Input Voltage | $V_{NGATE\_HV}$      | Above $V_{BATT}$ , $V_{BATT} > 35.5\text{V}$ , $I_{NGATE} = 1\mu\text{A}$   | -0.2 |      | 0    | V             |
| BATT HV Comparator Threshold               | $V_{LD\_THR}$        | BATT voltage rising   | 33   |      | 36   | V             |
| BATT HV Comparator Hysteresis              | $V_{LD\_HYS}$        |   |      | 0.7  |      | V             |
| NGATE Start Delay                          | $t_{NG\_DEL}$        | Delay between NGATE charge-pump turning on and BSTMON rising  |      | 2    | 2.2  | ms            |
| BATT-SENSE Overcurrent Threshold           | $V_{BATT\_SNS}$      |   | 190  | 200  | 210  | mV            |
| SENSE Input Bias Current                   | $I_{SNS}$            |   |      | 10   | 16   | $\mu\text{A}$ |
| BATT-SENSE Overcurrent Turnoff Delay       | $t_{SD\_SNS}$        |   |      | 4    |      | ms            |
| <b>RT OSCILLATOR</b>                       |                      |   |      |      |      |               |
| Switching Frequency Range                  | $f_{SW\_RT}$         | Frequency dithering disabled  | 400  |      | 2200 | kHz           |
| Oscillator Frequency Accuracy              |                      | $I_{RT} = 13.85\mu\text{A}$ ( $f_{SW} = 400\text{kHz}$ ),<br>$I_{RT} = 76.1\mu\text{A}$ ( $f_{SW} = 2200\text{kHz}$ ) | -10  |      | +10  | %             |

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| PARAMETER  | SYMBOL                 | CONDITIONS   | MIN   | TYP     | MAX   | UNITS         |
|--|------------------------|--|-------|---------|-------|---------------|
| Boost Converter Maximum Duty Cycle, High Frequency |                        | $f_{\text{SW}} = 1.8\text{MHz to } 2.2\text{MHz}$                        | 89    | 92      | 95    | %             |
| Boost Converter Maximum Duty Cycle, Low Frequency  |                        | $f_{\text{SW}} = 400\text{kHz to } 500\text{kHz}$                        | 94    |         | 98    | %             |
| Boost Minimum On-Time                              |                        |  |       | 60      |       | ns            |
| Frequency Dither, High Setting                     |                        | SSL = 1  |       | $\pm 6$ |       | %             |
| Frequency Dither, Low Setting                      | SS                     | SSL = 1  |       | $\pm 4$ |       | %             |
| RT Output Voltage                                  | $V_{\text{RT}}$        | $R_{\text{RT}} = 65\text{k}\Omega$ or $R_{\text{RT}} = 10\text{k}\Omega$ | 0.875 | 0.9     | 0.925 | V             |
| Sync Threshold                                     | $V_{\text{RT\_SYNC}}$  | $V_{\text{RT}}$ rising   | 0.77  |         | 0.84  | V             |
| Sync Frequency Duty Cycle                          | $D_{\text{SYNC}}$      |  |       | 50      |       | %             |
| Sync Frequency Range                               |                        |  | 400   |         | 2200  | kHz           |
| <b>SLOPE COMPENSATION</b>                          |                        |  |       |         |       |               |
| Peak Slope Compensation Current Ramp Magnitude     |                        | Current ramp added to CS   | 42    | 50      | 58    | $\mu\text{A}$ |
| <b>CURRENT-LIMIT COMPARATOR</b>                    |                        |  |       |         |       |               |
| CSP Threshold Voltage                              | $V_{\text{CSP-CSNL}}$  | $bl\_ilim = 1$   | 275   | 300     | 325   | mV            |
|  | $V_{\text{CSP-CSN}}$   | $bl\_ilim = 0$   | 380   | 410     | 440   |               |
| CSP Threshold Voltage During Low Voltage           | $V_{\text{CSP-LV}}$    | $V_{\text{BATT}} < V_{\text{BATT\_LVF}}$ , $V_{\text{BATT}}$ falling     | 560   | 600     | 640   | mV            |
| CSP Input Current                                  | $I_{\text{CSP}}$       | $V_{\text{EN}} = 0\text{V}$ , $V_{\text{CSP}} = 0.4\text{V}$             |       |         | 1     | $\mu\text{A}$ |
| <b>ERROR AMPLIFIER</b>                             |                        |  |       |         |       |               |
| OUT_Regulation High Threshold                      |                        | $V_{\text{OUT\_falling}}$  | 0.82  | 0.85    | 0.87  | V             |
| OUT_Regulation Low Threshold                       |                        | $V_{\text{OUT\_rising}}$   | 0.55  | 0.58    | 0.61  | V             |
| Transconductance                                   |                        |  | 410   | 630     | 890   | $\mu\text{S}$ |
| COMP Sink Current                                  |                        | $V_{\text{COMP}} = 1\text{V}$  | 270   | 380     | 500   | $\mu\text{A}$ |
| COMP Source Current                                |                        | $V_{\text{COMP}} = 1\text{V}$  | 270   | 380     | 500   | $\mu\text{A}$ |
| <b>MOSFET DRIVER</b>                               |                        |  |       |         |       |               |
| NDRV On-Resistance, High Side                      |                        | $I_{\text{NDRV}} = 100\text{mA}$   |       | 1.5     | 3     | $\Omega$      |
| NDRV On-Resistance, Low Side                       |                        | $I_{\text{NDRV}} = -100\text{mA}$  |       | 1.2     | 2     | $\Omega$      |
| NDRV Rise Time                                     |                        | $C_{\text{NDRV}} = 1\text{nF}$   |       | 8       |       | ns            |
| NDRV Fall Time                                     |                        | $C_{\text{NDRV}} = 1\text{nF}$   |       | 8       |       | ns            |
| NDRVS Input Logic-Low                              | $V_{\text{IL\_NDRVS}}$ | $V_{\text{NDRVS}}$ falling   |       | 2       | 2.4   | V             |
| NDRVS Input Logic-High                             | $V_{\text{IH\_NDRVS}}$ | $V_{\text{NDRVS}}$ rising  | 2.55  | 3.3     |       | V             |
| NDRVS Input Current                                | $I_{\text{NDRVS}}$     | $V_{\text{NDRVS}} = 5\text{V}$   |       | 60      | 80    | $\mu\text{A}$ |

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| PARAMETER                                      | SYMBOL                | CONDITIONS  | MIN  | TYP  | MAX   | UNITS         |
|--|-----------------------|---|------|------|-------|---------------|
| <b>LED CURRENT SINKS</b>                       |                       |   |      |      |       |               |
| IREF Output Voltage                            | $V_{IREF}$            | $I_{IREF} = 40\text{mA}$  | 0.86 | 0.88 | 0.9   | V             |
| IREF Out-of-Range Threshold                    | $I_{REFOOR}$          |   | 11   |      | 17.6  | $k\Omega$     |
| Full-Scale OUT_ Output Current                 | $I_{OUT225}$          | $R_{IREF} = 22k\Omega$ , 225mA setting  | 217  | 225  | 231   | mA            |
|  | $I_{OUT100}$          | $R_{IREF} = 22k\Omega$ , 100mA setting  | 97.5 | 100  | 103.5 |               |
| Current Regulation Between Strings             | $I_{OUT\_MATCH25}$    | $I_{OUT\_} = 225\text{mA}$  | -2.5 |      | +2.5  | %             |
| Current-Setting Resolution                     | $I_{OUT\_LSB}$        |   |      | 1.5  |       | mA            |
| OUT_ Leakage Current                           | $I_{OUT\_LEAK1}$      | $TON\_MM\_DIS = 1$<br>$V_{OUT\_} = 36\text{V}$ , DIM = 0, any OUT pin                             |      | 1    | 3     | $\mu\text{A}$ |
|  | $I_{OUT\_LEAK25}$     | $TON\_MM\_DIS = 1$<br>$V_{OUT\_} = 36\text{V}$ , DIM = 0, any OUT_ pin, $T_A = +25^\circ\text{C}$ |      |      | 1     | $\mu\text{A}$ |
|  | $I_{OUT\_LEAK0}$      | $TON\_MM\_DIS = 0$  |      | 75   | 100   |               |
| OUT_ Minimum Pulse Width                       | $t_{OUT\_}$           |   |      | 300  |       | ns            |
| OUT_ Minimum Negative Pulse Width              |                       |   |      | 90   |       | ns            |
| $I_{OUT\_}$ Rise Time                          | $I_{OUT\_TR}$         | 10% to 90% $I_{OUT\_}$  |      | 150  |       | ns            |
| $I_{OUT\_}$ Fall Time                          | $I_{OUT\_TF}$         | 90% to 10% $I_{OUT\_}$  |      | 20   |       | ns            |
| <b>DIM INPUT</b>                               |                       |   |      |      |       |               |
| DIM Frequency Range                            |                       |   | 90   |      | 50000 | Hz            |
| DIM Sampling Frequency                         |                       |   |      | 20   |       | MHz           |
| <b>FAULT DETECTION</b>                         |                       |   |      |      |       |               |
| LED Short-Detection Threshold                  | $V_{THSHRT}$          | SLDET[1:0] = 11   | 7.7  | 8    | 8.1   | V             |
|  |                       | SLDET[1:0] = 10   | 5.6  | 6    | 6.4   |               |
|  |                       | SLDET[1:0] = 01   | 2.8  | 3    | 3.2   |               |
| OUT_ Check-LED-Source Current                  | $I_{OUT\_CKLED}$      | $V_{OUT\_} = 0.5\text{V}$   | 45   | 60   | 75    | $\mu\text{A}$ |
| OUT_ Short-to-GND Detection Threshold          | $V_{OUT\_GND}$        | $V_{OUT\_}$ falling   | 230  | 250  | 270   | mV            |
| OUT_ Unused-Detection High Threshold           | $V_{OUT\_UN}$         |   | 0.8  | 0.85 | 0.9   | V             |
| OUT_ Open-LED-Detection Threshold              | $V_{OUT\_OPEN}$       |   | 230  | 250  | 270   | mV            |
| Shorted-LED-Detection Flag Delay               | $t_{SHRT}$            |   |      | 6.8  |       | $\mu\text{s}$ |
| <b>OVERVOLTAGE AND UNDERVOLTAGE PROTECTION</b> |                       |   |      |      |       |               |
| BSTMON Overvoltage Threshold                   | $V_{BSTMON\_OV}$      | $V_{BSTMON}$ rising   | 0.92 | 0.95 | 0.98  | V             |
| BSTMON Overvoltage Hysteresis                  | $V_{BSTMON\_OV\_HYS}$ |   |      | 50   |       | mV            |

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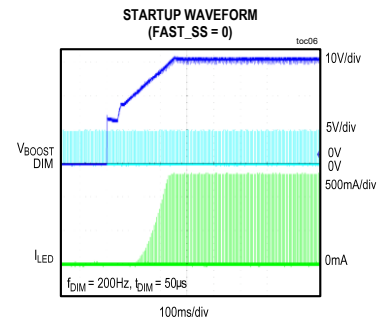
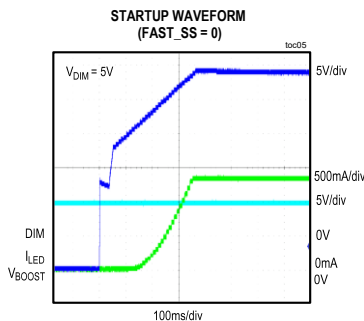
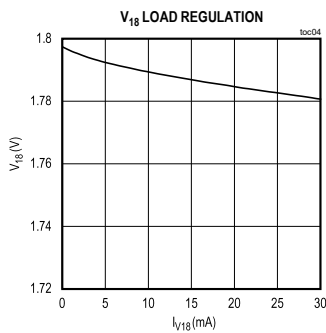
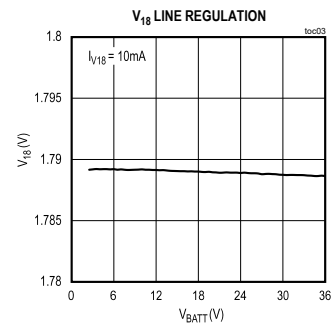
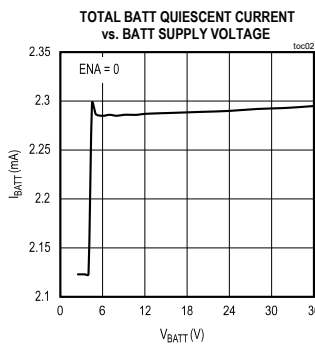
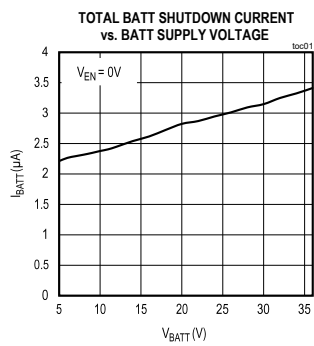
| PARAMETER   | SYMBOL                 | CONDITIONS   | MIN   | TYP   | MAX   | UNITS            |
|---|------------------------|--|-------|-------|-------|------------------|
| BSTMON Input Bias Current                                 | $I_{\text{BSTMON}}$    | $0 < V_{\text{BSTMON}} < 1\text{V}$  | -1    |       | +1    | $\mu\text{A}$    |
| BSTMON Undervoltage-Trip Threshold                        | $V_{\text{OVPUVLO}}$   | $V_{\text{BSTMON}}$ rising   | 0.38  | 0.4   | 0.412 | V                |
| Boost Undervoltage-Detection Delay                        | $\text{OVPUVLO\_BLK}$  |  |       | 10    |       | $\mu\text{s}$    |
| Boost Undervoltage-Blanking Time                          |                        | After soft-startup, $\text{fast\_ss} = 0$                                      | 49    | 53.25 | 57.5  | ms               |
|   |                        | After soft-start, $\text{fast\_ss} = 1$  | 26.28 | 28.46 | 30.74 |                  |
| <b>TEMP PIN</b>   |                        |  |       |       |       |                  |
| TEMP Pin Voltage  | $V_{\text{TEMP}}$      | $I_{\text{TEMP}} = -10\mu\text{A}$   | 380   | 400   | 420   | mV               |
| $I_{\text{TEMP}}$ to $I_{\text{OUT\_Gain}}$               |                        | $V_{\text{TEMP}} < 400\text{mV}$   |       | 0.67  |       | $\%/\mu\text{A}$ |
| TEMP Pin Disable Threshold                                |                        |  |       | 0.5   |       | V                |
| TEMP Pin Leakage Current                                  |                        |  |       | 0.005 | 0.5   | $\mu\text{A}$    |
| TEMP Current for LED Current Disable                      | $I_{\text{TEMPD}}$     |  |       | 125   |       | $\mu\text{A}$    |
| <b>LOGIC INPUTS AND OUTPUTS (EN, SCL, SDA, DIM, FLTB)</b> |                        |  |       |       |       |                  |
| Digital Inputs Logic-High                                 | $V_{\text{IH}}$        |  | 1.22  |       |       | V                |
| Digital Inputs Logic-Low                                  | $V_{\text{IL}}$        |  |       |       | 0.6   | V                |
| Digital Inputs Hysteresis                                 | $V_{\text{HYS}}$       |  |       | 300   |       | mV               |
| EN Input Pull-Down Resistor                               | $R_{\text{PDEN}}$      |  | 100   | 165   | 240   | $\text{k}\Omega$ |
| EN Blanking Time  | $t_{\text{EN\_BLK}}$   |  |       | 10    |       | $\mu\text{s}$    |
| DIM, ADD, and MODE Pull-up Current                        | $I_{\text{DIN\_PUP}}$  | $V_{\text{DIN}} = 0\text{V}$   |       | 2     |       | $\mu\text{A}$    |
| DIM Frequency Range                                       |                        |  | 90    |       |       | Hz               |
| DIM Sampling Frequency                                    |                        |  | 18    | 20    | 22    | MHz              |
| SCL Input Current   | $I_{\text{DIN}}$       | $V_{\text{DIN}} = +5\text{V}$  |       |       | 1     | $\mu\text{A}$    |
| FLTB, SDA Output Low Voltage                              | $V_{\text{OL\_OUT}}$   | $I_{\text{FLTB}} = I_{\text{SDA}} = 5\text{mA}$                                |       |       | 0.4   | V                |
| FLTB, SDA Output Leakage Current                          | $I_{\text{OUT\_LEAK}}$ | $V_{\text{EN}} = 0\text{V}$ , $V_{\text{FLTB}} = V_{\text{SDA}} = 5.5\text{V}$ |       |       | 1     | $\mu\text{A}$    |
| <b>THERMAL SHUTDOWN</b>                                   |                        |  |       |       |       |                  |
| Thermal-Shutdown Threshold                                |                        |  |       | 160   |       | $^\circ\text{C}$ |
| Thermal-Shutdown Hysteresis                               |                        |  |       | 17    |       | $^\circ\text{C}$ |
| Thermal Warning Threshold                                 |                        |  |       | 125   |       | $^\circ\text{C}$ |
| <b>I<sup>2</sup>C INTERFACE</b>                           |                        |  |       |       |       |                  |
| Clock Frequency   | $f_{\text{SCL}}$       |  |       |       | 0.4   | MHz              |
| Hold Time (Repeated) START                                | $t_{\text{HD:STA}}$    |  | 600   |       |       | ns               |
| SCL Low Time  | $t_{\text{LOW}}$       |  | 1300  |       |       | ns               |

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| PARAMETER                     | SYMBOL              | CONDITIONS | MIN | TYP | MAX | UNITS |
|-------------------------------|---------------------|------------|-----|-----|-----|-------|
| SCL High Time                 | $t_{\text{HIGH}}$   |            | 600 |     |     | ns    |
| Setup Time (Repeated) START   | $t_{\text{SU:STA}}$ |            | 600 |     |     | ns    |
| Data Hold Time                | $t_{\text{HD:DAT}}$ |            | 0   |     |     | ns    |
| Data Setup Time               | $t_{\text{SU:DAT}}$ |            | 100 |     |     | ns    |
| Setup Time for STOP Condition | $t_{\text{SU:STO}}$ |            | 600 |     |     | ns    |
| Spike Suppression             |                     |            |     | 50  |     | ns    |

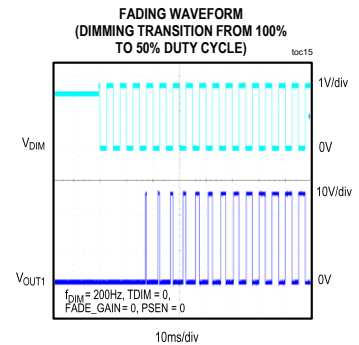
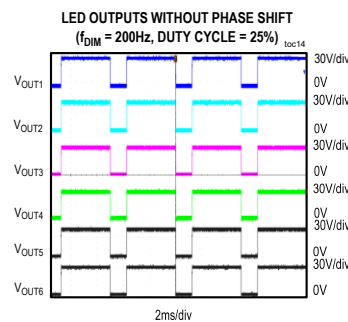
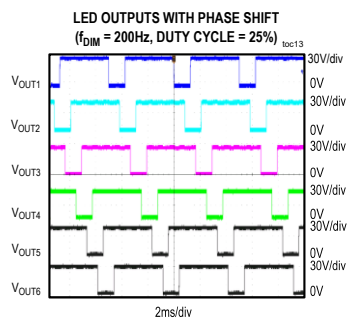
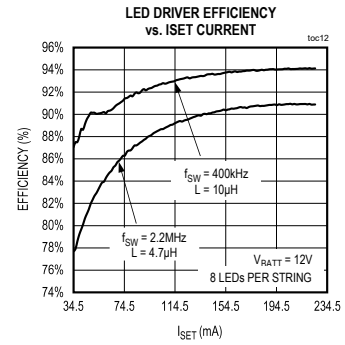
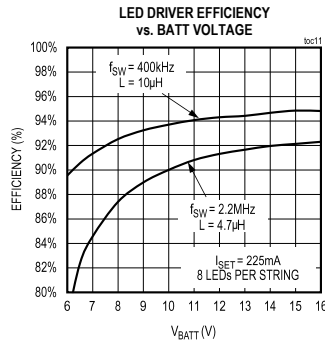
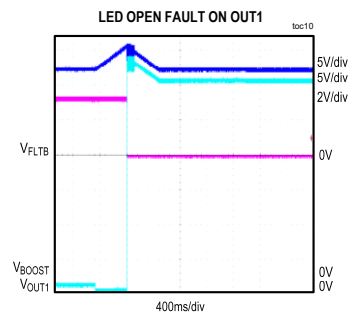
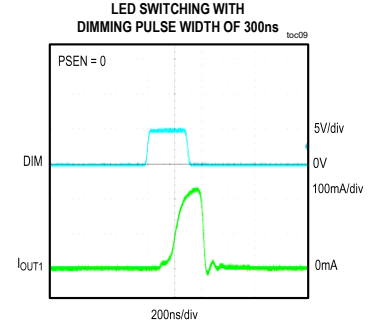
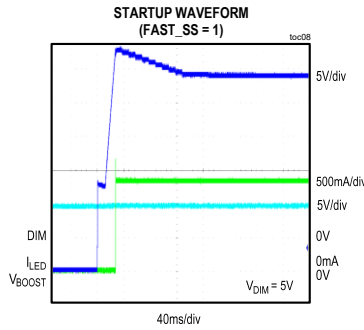
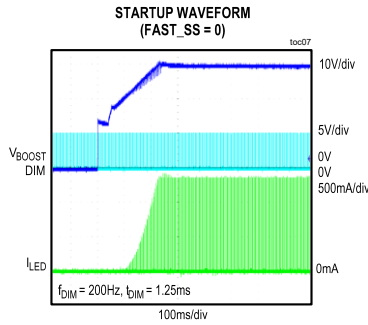
### Typical Operating Characteristics

( $V_{\text{IN}} = V_{\text{EN}} = 12\text{V}$ , 6x9 LED load at 200mA,  $f_{\text{SW}} = 2.2\text{MHz}$ ,  $T_A = +25^\circ\text{C}$  unless otherwise noted.)

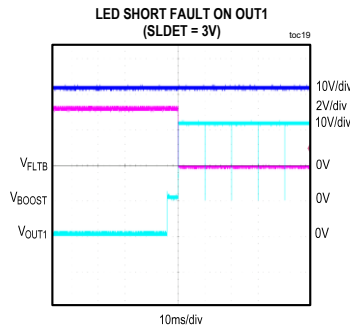
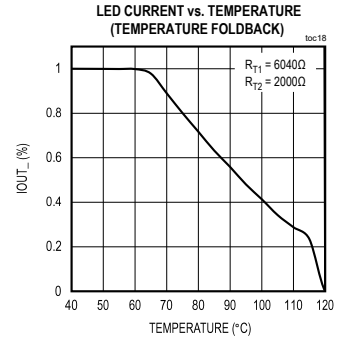
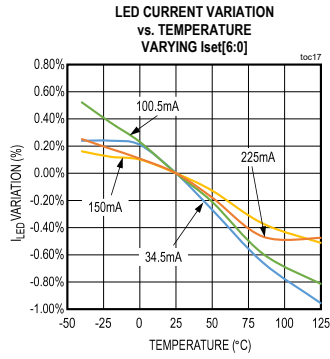
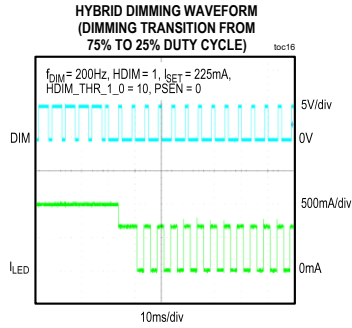




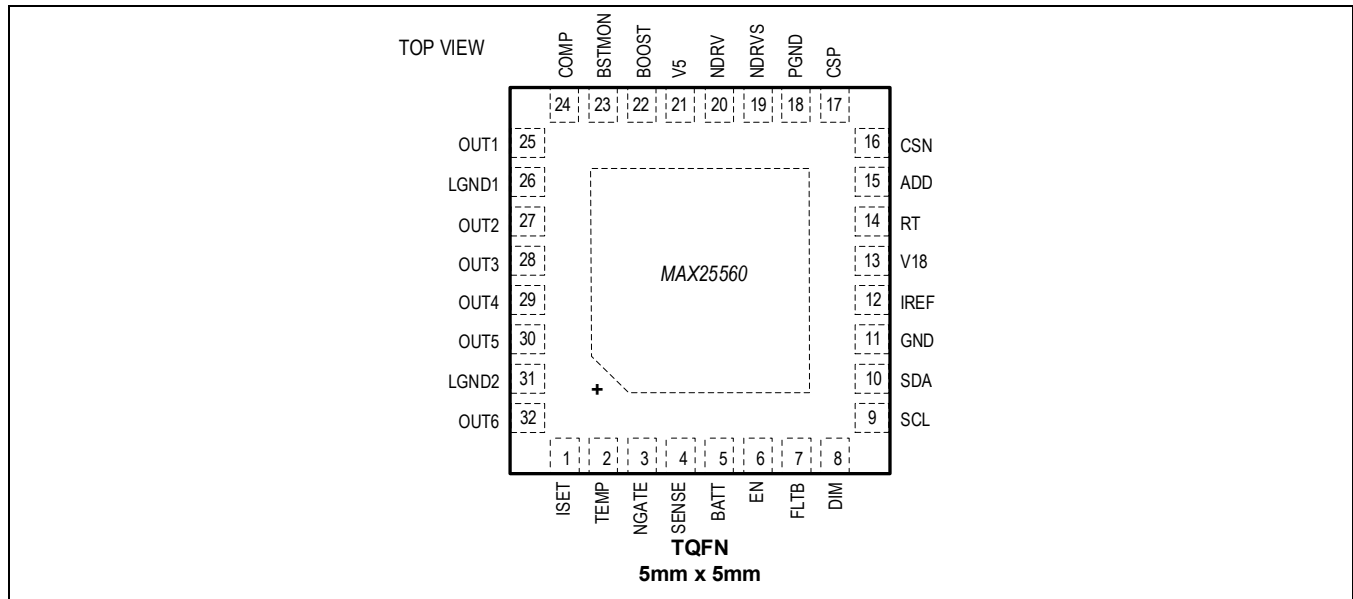
( $V_{IN} = V_{EN} = 12V$ , 6x9 LED load at 200mA,  $f_{SW} = 2.2MHz$ ,  $T_A = +25^{\circ}C$  unless otherwise noted.)



( $V_{IN} = V_{EN} = 12V$ , 6x9 LED load at 200mA,  $f_{SW} = 2.2MHz$ ,  $T_A = +25^\circ C$  unless otherwise noted.)



## Pin Configurations

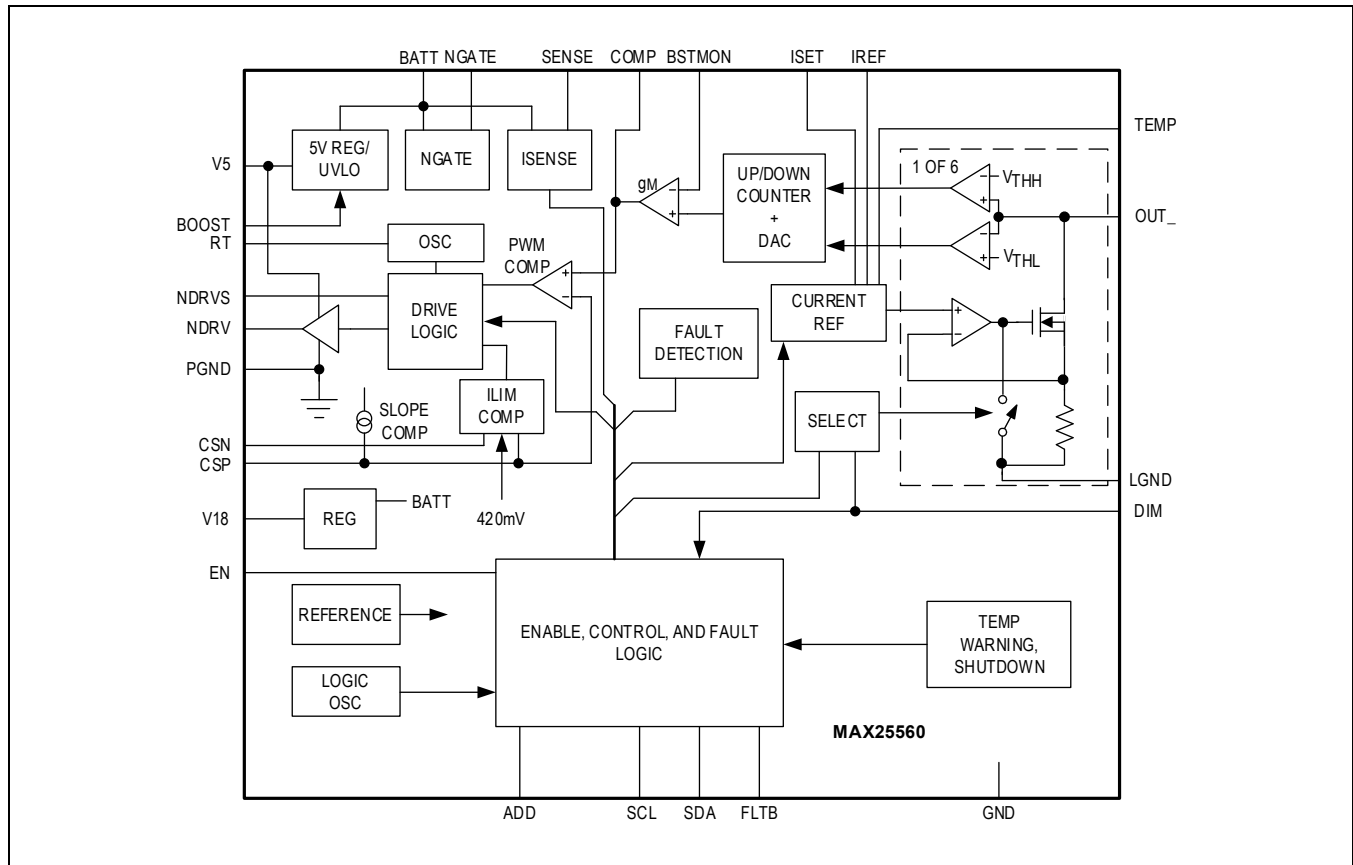


## Pin Descriptions

| PIN | NAME  | FUNCTION   |
|-----|-------|--|
| 1   | ISET  | Startup LED Current Setting Pin. Connect a resistor to this pin to set the initial LED current in each of the channels and enable startup when the EN pin is taken high. LED current can be adjusted by writing to the ISET_REG register after startup. If using I <sup>2</sup> C to set the LED current and enable the device, connect the ISET pin to V18. |
| 2   | TEMP  | Temperature Sensor Input. To implement LED current reduction at high temperatures, connect an NTC temperature sensor to GND with resistors from the NTC to TEMP and V18. If unused, connect TEMP to V18.   |
| 3   | NGATE | Gate Connection for External Series nMOSFET Driven by the Internal Charge Pump   |
| 4   | SENSE | Boost Input Current Sense Input. Connect to a sense resistor in series with the boost input. If unused, connect SENSE to BATT.   |
| 5   | BATT  | LED Driver Supply Input. Connect BATT to a 4.5V to 40V supply. Bypass BATT to ground with ceramic capacitors of 2.2mF and 0.1nF.   |
| 6   | EN    | Enable Input. When EN is high, the device is enabled. When EN is low, the device is in shutdown with low quiescent current. EN has an internal pull-down resistor.   |
| 7   | FLTB  | Active-Low, Open-Drain Fault Indication Output. Connect an external pull-up resistor from FLTB to an external supply lower than 5V.  |
| 8   | DIM   | PWM Dimming Input. DIM has an internal pull-up to V18.   |
| 9   | SCL   | I <sup>2</sup> C Clock Input   |
| 10  | SDA   | I <sup>2</sup> C Data I/O  |
| 11  | GND   | Ground Connection  |
| 12  | IREF  | Reference Current Set Pin. Connect a 1% resistor of value 22kΩ from IREF to GND.   |
| 13  | V18   | Output of Internal 1.8V Regulator. Connect a 2.2μF capacitor from V18 to GND with an additional 100nF capacitor close to the V18 and GND pins.   |
| 14  | RT    | Frequency Setting Resistor for Backlight Boost Converter   |
| 15  | ADD   | Device Address Select Pin. Connect to GND or V18 to select the device I <sup>2</sup> C address. See <a href="#">Table 3</a> . ADD has an internal pull-up to V18.  |
| 16  | CSN   | LED Driver MOSFET Negative Current-Sense Connection. Connect this pin directly to the GND side of the compensation network connected to the COMP pin.  |

|    |        |  |
|----|--------|--|
| 17 | CSP    | LED Driver MOSFET Positive Current-Sense Connection. Connect a sense resistor from the MOSFET source to PGND and a further resistor from the MOSFET source to the CSP pin to set the slope compensation (see the <a href="#">Current-Sense Resistor and Slope Compensation</a> section). |
| 18 | PGND   | Power Ground Connection  |
| 19 | NDRVS  | Sense Connection for Gate of External MOSFET. Connect NDRVS directly to the gate after the gate resistor.  |
| 20 | NDRV   | Switching nMOSFET Gate-Driver Output. Connect NDRV to the gate of the external switching power MOSFET. Typically, a small resistor (1Ω to 22Ω) is inserted between the NDRV output and nMOSFET gate to decrease the slew rate of the gate driver and reduce the switching noise.         |
| 21 | V5     | 5V Regulator Output, Voltage Supply for NDRV Gate Driver. Place 2.2μF and 22nF ceramic capacitors as close as possible to the device, between V5 and GND.  |
| 22 | BOOST  | Boost Output Voltage Connection. BOOST is used to supply power to the V <sub>CC</sub> regulator when the IN voltage is too low. Bypass with a 0.1mF capacitor placed close to the pin.   |
| 23 | BSTMON | LED Driver Output-Voltage-Sensing Input. This voltage is used for overvoltage and undervoltage protection. Connect a resistor-divider between the boost converter output, BSTMON pin, and GND.   |
| 24 | COMP   | LED Driver Switching-Converter Compensation Input. Connect an RC network from COMP to GND to compensate the backlight boost converter.   |
| 25 | OUT1   | LED String 1 Cathode Connection. Do not connect more than 470pF of capacitance from OUT1 to GND.   |
| 26 | LGND1  | LED Ground Connection  |
| 27 | OUT2   | LED String 2 Cathode Connection. Connect OUT2 to ground using a 9.1kΩ resistor if not used. Do not connect more than 470pF of capacitance from OUT2 to GND.  |
| 28 | OUT3   | LED String 3 Cathode Connection. Connect OUT3 to ground using a 9.1kΩ resistor if not used. Do not connect more than 470pF of capacitance from OUT3 to GND.  |
| 29 | OUT4   | LED String 4 Cathode Connection. Connect OUT4 to ground using a 9.1kΩ resistor if not used. Do not connect more than 470pF of capacitance from OUT4 to GND.  |
| 30 | OUT5   | LED String 5 Cathode Connection. Connect OUT4 to ground using a 9.1kΩ resistor if not used. Do not connect more than 470pF of capacitance from OUT5 to GND.  |
| 31 | LGND2  | LED Ground Connection  |
| 32 | OUT6   | LED String 6 Cathode Connection. Connect OUT4 to ground using a 9.1kΩ resistor if not used. Do not connect more than 470pF of capacitance from OUT6 to GND.  |
| —  | EP     | Exposed Pad. Connect to a large contiguous copper-ground plane for optimal heat dissipation. Do not use EP as the only electrical ground connection.   |

## Functional Diagrams



## Detailed Description

The MAX25560 is a six-channel LED backlight driver with an integrated current-mode boost controller which operates over a switching frequency range of 400kHz to 2.2MHz and incorporates spread spectrum. Selectable phase-shifting of the output channels is included to reduce EMI. The MAX25560 provides up to 220mA per channel. The device is capable of operating down to very low battery voltages while maintaining 5V drive for the external MOSFET at NDRV.

Extensive diagnostics and an I<sup>2</sup>C interface are included in the device.

The MAX25560 is available in a compact TQFN package and operates over the -40°C to +125°C temperature range.

### Undervoltage Lockout

The device features three undervoltage circuits that monitor the input voltage at BATT and the outputs of the internal LDO regulators at V5 and V18. The backlight boost can be enabled only when BATT, V5, and V18 exceed their respective UVLO thresholds.

### Low-Voltage Operation

After the boost soft-start is completed, the MAX25560 continues to operate with BATT voltages lower than 5V while maintaining 5V drive for the external MOSFET at NDRV. When the voltage at BATT drops to  $V_{BATT\_LVF}$ , the V5 regulator switches its input from BATT to BOOST, the boost converter current limit is automatically increased to  $V_{CSP\_LV}$ , and the switching frequency is reduced if it is greater than 1.4MHz. Switchover occurs as long as the voltage on BOOST is above  $V_{BATT\_LVF}$ . In this mode, if the standard current limit is exceeded on four consecutive cycles, a 100ms timer is started, which returns the current limit to its original value when it expires.

When BATT returns to a voltage above  $V_{BATT\_LVR}$ , the V5 regulator resumes operation from BATT and the converter current limit and switching frequency return to their former values. Bypass BATT and BOOST with ceramic capacitors placed close to the respective pins.

At very low input voltages, the efficiency of the boost converter decreases, and the input current can reach very high levels as a consequence. The external boost converter components must be selected for worst-case operation. An alternative is to reduce the output power at low input voltages.

If the voltage at BATT drops below the undervoltage lockout level ( $V_{BATT\_UVF}$ ) at any time, the boost converter is disabled.

### Input Current Monitoring

Input overcurrent protection is implemented by using an external sense resistor connected between BATT and SENSE. If the voltage across the sense resistor exceeds 200mV after the 2ms NGATE turn-on phase (Stage 1 of startup) for a time greater than 4 $\mu$ s, the boost converter is latched off, the ISNS\_SD bit in the DIAG2\_REG register is set, and the FLTB pin is asserted low. The shutdown function can be disabled by setting the DIS\_ISNS\_SD bit to 1. In that case, the device continues operation when an input overcurrent is detected; the ISNS\_SD bit is set, but FLTB does not assert low.

To reenable the device, toggle the power supply, the EN input pin, or the ENA bit.

The value of the voltage between BATT and SENSE is continuously sampled by the internal ADC, and the most recent value can be read from the VSENSE register.

### Oscillator Frequency/External Synchronization

The internal oscillator frequency is programmable between 400kHz and 2.2MHz using a timing resistor ( $R_{RT}$ ) connected from the RT pin to GND. Use the following equation to calculate the value of  $R_{RT}$  for the desired switching frequency ( $f_{SW}$ ):

$$R_{RT} = \frac{26130}{f_{SW}} + 0.33$$

where  $R_{RT}$  is in k $\Omega$  and  $f_{SW}$  is in kHz. If the value of the RT resistor is too low or if the pin is shorted to GND, the boost converter will not start and the FLTB pin will go low.

To synchronize the oscillator with an external clock, AC-couple the external clock to the RT input. The value of the capacitor used for AC-coupling is  $C_{SYNC} = 10\text{pF}$ , and the duty cycle of the external clock should be 50%. When synchronizing the converter, do not apply the synchronizing signal to the RT pin at startup, as this may cause the RT resistor value check to fail.

At low input voltages and when the switching frequency is above 1MHz, the switching frequency is automatically reduced to enable high-duty-cycle operation and maintain output voltage regulation. This applies also when the device is synchronized to an external frequency.

### Spread Spectrum

The IC includes spread-spectrum modulation that reduces peak electromagnetic interference (EMI) at the switching frequency and its harmonics. Spread spectrum can be enabled and disabled using the SS\_OFF bit in the register SETTING\_REG.

Spread spectrum uses a pseudorandom dithering technique where the switching frequency is varied in the range of 94% to 106% or 96% to 104% (depending on the setting of the SSL bit) of the programmed switching frequency set through the external resistor from RT to GND. When spread spectrum is used, the total energy at the fundamental and each harmonic is spread over a wider bandwidth, thus reducing the peak energy at the relevant frequency.

Spread spectrum is disabled if external synchronization is used.

### LED Current Control

The IC features six identical constant-current sources used to drive multiple high-brightness LED strings. The current through each of the channels is adjustable between 34.5mA and 225mA by setting the 7-bit value  $iset[6:0]$  in the ISET\_REG register.

To accelerate device startup, the initial LED current can be set by connecting a resistor from the ISET pin to GND. With this resistor present, the ENA bit is initialized to 1, and the device starts up immediately when the EN pin is taken high. A

current value determined by the resistor on ISET is loaded into the `iset[6:0]` field in `ISET_REG` and can be adjusted subsequently using the I<sup>2</sup>C interface. Select the ISET resistor value using [Table 1](#).

**Table 1. ISET Resistor Value for a Given LED Current**

| ISET RESISTOR (kΩ) | LED CURRENT PER CHANNEL (mA) | CORRESPONDING ISET REGISTER VALUE |
|--------------------|------------------------------|-----------------------------------|
| 4.3                | 96                           | 0x29                              |
| 9.1                | 106.5                        | 0x30                              |
| 15                 | 118.5                        | 0x38                              |
| 24                 | 130.5                        | 0x40                              |
| 33                 | 145.5                        | 0x4A                              |
| 43                 | 162                          | 0x55                              |
| 56                 | 180                          | 0x61                              |
| 68                 | 199.5                        | 0x6E                              |

Multiple channels can be paralleled together for string currents exceeding 225mA.

### Current-Mode DC-DC Controller

The device contains a constant-frequency, current-mode controller designed to drive the LEDs in a boost or SEPIC configuration. The IC features multiloop control to regulate the peak current in the inductor, as well as the voltage across the LED current sinks to minimize power dissipation.

Programmable slope compensation is used to avoid subharmonic oscillation that can occur at > 50% duty cycles in continuous-conduction mode.

The external nMOSFET is turned on at the beginning of every switching cycle. The inductor current ramps up linearly until turned off at the peak current level set by the feedback loop. The peak inductor current is sensed from the voltage across the current-sense resistor ( $R_{CS}$ ), which is connected from the source of the external nMOSFET to PGND.

The IC features leading-edge blanking to suppress the external nMOSFET switching noise. A PWM comparator compares the current-sense voltage plus the slope-compensation signal with the output of the transconductance error amplifier. The controller turns off the external nMOSFET when the voltage at CSP exceeds the error amplifier's output voltage (at the COMP pin). This process repeats every switching cycle to achieve peak current-mode control.

In addition to the peak current-mode-control loop, the IC has two other feedback loops for control. The converter output voltage is sensed through the BSTMON input, which is connected to the inverting input of the error amplifier. The BSTMON gain ( $A_{OVP}$ ) is defined as  $V_{OUT}/V_{BSTMON}$ , or  $(R17 + R16)/R16$ . The other feedback comes from the OUT\_ current sinks. This loop controls the headroom of the current sinks to minimize total power dissipation, while still ensuring accurate LED current. Each current sink has a window comparator with a low threshold of 0.58V and a high threshold of 0.85V. These comparators drive logic that controls an up/down counter. The up/down counter is updated on every falling edge of the DIM input and drives an 8-bit digital-to-analog converter (DAC), which sets the reference to the error amplifier.

### 9-Bit DAC

The error amplifier's reference input is controlled with an 9-bit DAC. The DAC output is ramped up during startup to implement a soft-start function (see the [Startup Sequence](#) section). During normal operation, the DAC output range is limited to between 0.482V and 0.996V. Because the DAC output is limited to no less than 0.482V during normal operation, the overvoltage threshold for the output should be set to a value less than twice the minimum LED forward voltage. The DAC LSB determines the minimum output-voltage step according to the following equation:

$$V_{STEP\_MIN} = V_{DAC\_LSB} \times A_{OVP}$$

where  $V_{STEP\_MIN}$  is the minimum output-voltage step,  $V_{DAC\_LSB}$  is 1.95mV (typ), and  $A_{OVP}$  is the BSTMON resistor-divider gain ( $1 + R6/R7$ ).

## Startup Sequence

The boost converter startup sequence occurs in three stages, as described in the Stage 1, Stage 2, and Stage 3 sections. The overall startup time can be selected using the `fast_ss` bit in the `BL_CONFIG1` register when using the I<sup>2</sup>C interface. The boost output voltage at the end of Stage 2 differs between the slow and fast startup modes.

### Stage 1

After the `ENA` bit has been set to 1, the controller turns on the `NGATE` charge pump for the external nMOSFET if the `V5` and `BATT` voltages are above their respective undervoltage thresholds. The output current of the charge pump charges the gate of the external nMOSFET, thus turning it on. After a 2ms timeout expires, Stage 2 of the startup begins. If `NGATE` is unused, set the `CP_DIS` bit in the `DISABLE_REG` register to disable the `NGATE` charge pump.

### Stage 2

After the external MOSFET on `NGATE` has been enabled, the IC goes through its power-up checks, including unused string detection and `OUT_` short-to-ground detection. To avoid possible damage, the converter does not start if any `OUT_` is detected as shorted to ground.

Any current sinks detected as unused are disabled to prevent a false fault-flag assertion during normal operation. After these checks have been performed, the converter begins to operate and the output voltage begins to ramp up. The DAC reference to the error amplifier is stepped upwards until the `OVP` pin reaches 0.48V (or 0.88V in fast startup mode).

This stage duration is fixed at approximately 50ms (22ms in fast startup mode).

### Stage 3

The third stage begins once the second stage is complete and the `DIM` input goes high. During Stage 3, the output of the converter is adjusted until the minimum `OUT_` voltage falls within the window comparator limits of 0.58V (typ) and 0.85V (typ). The output ramp is again controlled by the DAC, which provides the reference for the error amplifier. The DAC output is updated on each rising edge of the `DIM` input. If the `DIM` input is a 100% duty cycle (`DIM` = high), then the DAC output is updated once every 10ms.

The total soft-start time can be calculated using the following equation in slow-startup mode:

$$t_{SS} = 50ms + \frac{V_{LED} + 0.87 - (0.48 \times A_{OVP})}{f_{DIM} \times 0.01 \times A_{OVP}}$$

where  $t_{SS}$  is the total soft-start time, 50ms is the fixed Stage 1 duration,  $V_{LED}$  is the total forward voltage of the LED strings, 0.81V is midpoint of the window comparator,  $A_{OVP}$  is the gain of the `OVP` resistor-divider,  $f_{DIM}$  is the dimming frequency (use 100Hz if the `DIM` input duty cycle is 100%), and 0.01V is the maximum voltage step per clock cycle of the DAC.

In fast-startup mode (when the `FAST_SS` bit in the `SET_REG` register is set to 1), the following equation should be used:

$$t_{SS} = 25ms + \frac{0.88 \times A_{OVP} - (V_{LED} + 0.87)}{f_{DIM} \times 0.01 \times A_{OVP}}$$



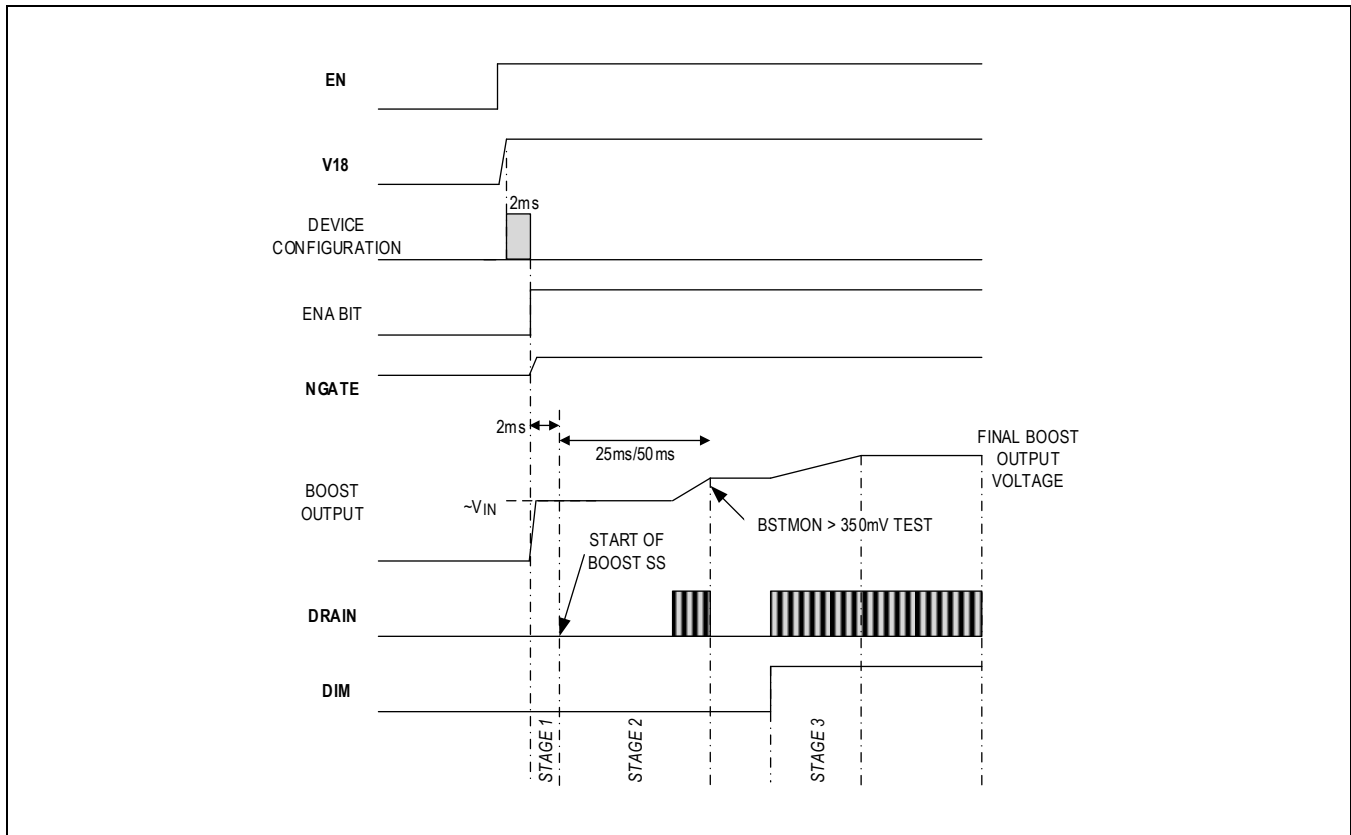


Figure 1. Start-up Sequence

## Dimming

Dimming can be performed using an external PWM signal applied to the DIM pin or by writing to the TONn\_REG registers, where n is the number of the OUT\_ pin (after setting the DIM\_EXT bit to 0). When the TON\_ALL bit is set to 1, the TON1\_ value is used for all active outputs.

The signal on the DIM pin is sampled with a 20MHz internal clock, except when phase-shifting is disabled, in which case the DIM signal controls the OUT\_ outputs directly.

### Low-Dimming Mode

The IC's operation changes at very narrow dimming pulses to ensure a consistent dimming response of the LEDs. If the dimming on-time is lower than 50 $\mu$ s (typ), the device enters low-dimming mode (which is indicated by the bits in the LO\_DIM register). In this state, the converter switches continuously and LED short detection is disabled. When the DIM input is greater than 51 $\mu$ s (typ) the device goes back into normal operation, enabling the short-LED detection and switching the power FET only when the effective dimming signal is high.

### Phase-Shift Dimming

When the PSEN bit in register SET\_REG is set to 1, phase-shifting of the LED strings is enabled. To achieve this, the DIM signal is sampled internally by a 20MHz clock. The device automatically sets the phase shift between strings to a value depending on the number of strings enabled.

When phase-shifting is enabled, the sampled DIM input is used to generate separate phase-shifted dimming signals for each LED string. The resolution with which the DIM signal is captured degrades at higher DIM input frequencies; therefore, dimming frequencies between 100Hz and 3kHz are recommended, although higher dimming frequencies are technically possible. The phase shift between strings is determined by the following equation:

$$\Theta = 360/n$$

where n is the total number of strings being used and  $\theta$  is the phase shift in degrees. See [Figure 2](#) for a timing diagram example with phase-shifting enabled.

When phase-shifting is disabled, all strings turn on/off at the same time controlled directly by the DIM input. If multiple current sinks are being connected in parallel, phase-shifting should be disabled.

If a fault is detected, resulting in a string being disabled during normal operation, the phase-shifting adjusts to the new situation.

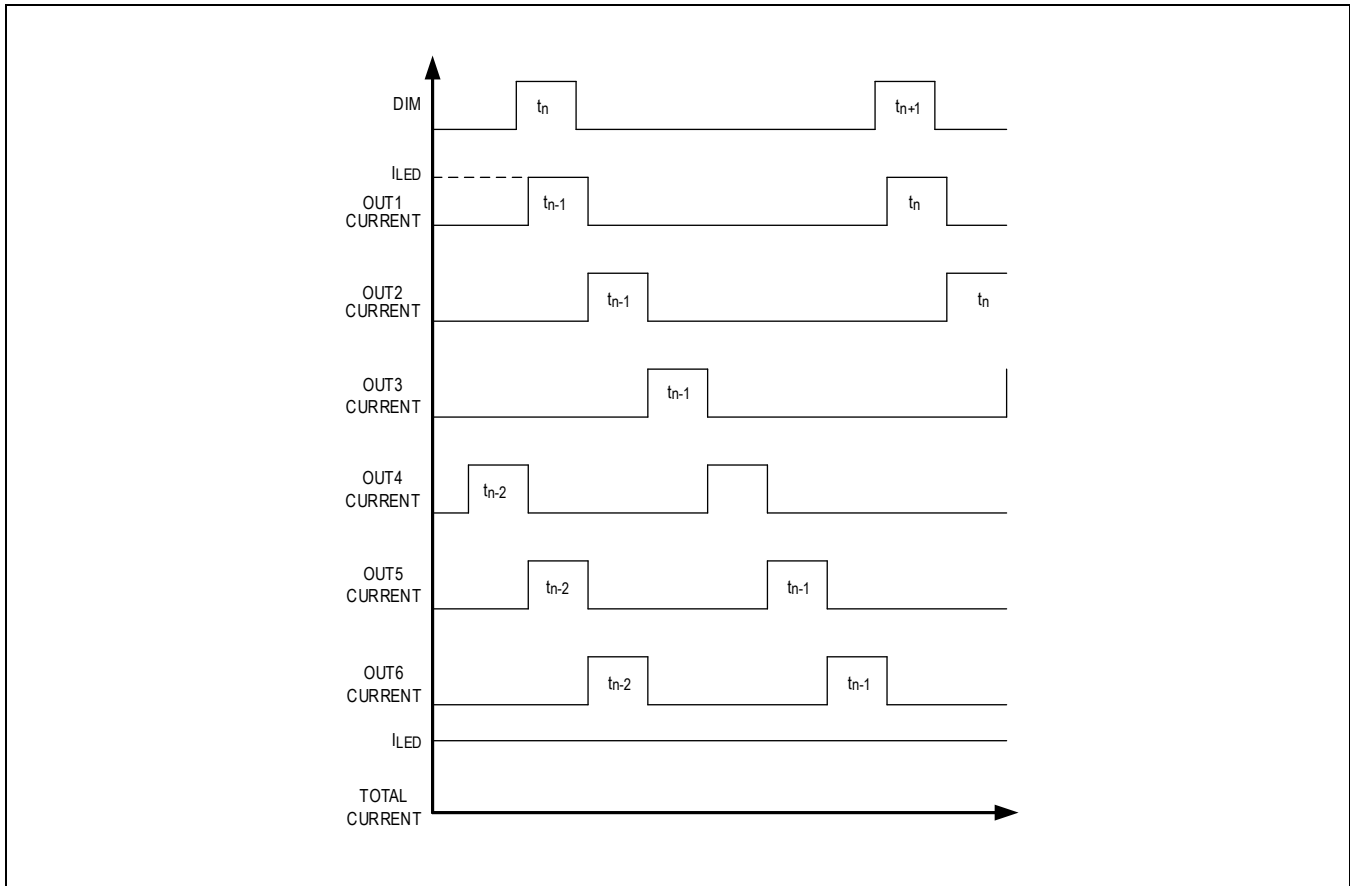


Figure 2. Phase-Shifted Outputs

### Automatic Fade-In/Fade-Out During Dimming

The device can be configured to perform a smooth change in brightness, even when the DIM input duty cycle or TON\_ setting is changed by setting the FADE\_IN\_OUT bit in the FADING\_REG register to 1.

When using the fade function, it is important to maintain the DIM frequency constant when entering 100% duty cycle. This is necessary in order to avoid erroneous frequency measurement, which could change the speed of the fade-in.

### Disabling Individual Strings

To disable an unused LED string, connect the unused OUT\_ to ground through a 9.1k $\Omega$  resistor, or set the corresponding DIS\_ bit to 1 in the DISABLE register before the ENA bit is set. During startup, the device sources 60 $\mu$ A (typ) current through the OUT\_ pins and measures the corresponding voltage. For the string to be properly disabled, the OUT\_ voltage should measure between the maximum value of V<sub>OUT\_GND</sub> and the minimum value of V<sub>OUT\_UN</sub> during this check.

**Note:** When disabling unused strings, it is necessary to start by disabling the highest numbered current sinks first (e.g., if two strings need to be disabled, disable OUT6 and OUT5. Do not disable any two strings at random). During normal operation, strings can be selectively turned off by changing the corresponding TON\_ setting to 0. This is only possible when internal dimming is used (not when using the DIM input pin).

### Hybrid Dimming

To invoke hybrid dimming mode, set the HDIM bit in register IMODE\_REG. In hybrid dimming mode, the external LEDs are dimmed by first reducing their current as the dimming duty cycle decreases from 100% (see [Figure 3](#)). At the crossover

level set by the HDIM\_THR\_1\_0[1:0] bits, dimming transitions to PWM dimming where the LED current is chopped. Depending on the DIM\_EXT bit, the device functions in one of two ways:

- (DIM\_EXT = 1) measures the duty cycle on the DIM pin and translates it into a combined LED current value and PWM setting.
- (DIM\_EXT = 0) takes the 18-bit value from the TON1 register and translates it into a combined LED current value and PWM setting.

Figure 3 illustrates the difference between standard and hybrid dimming with phase-shifting enabled.

**Hybrid Dimming Operation**

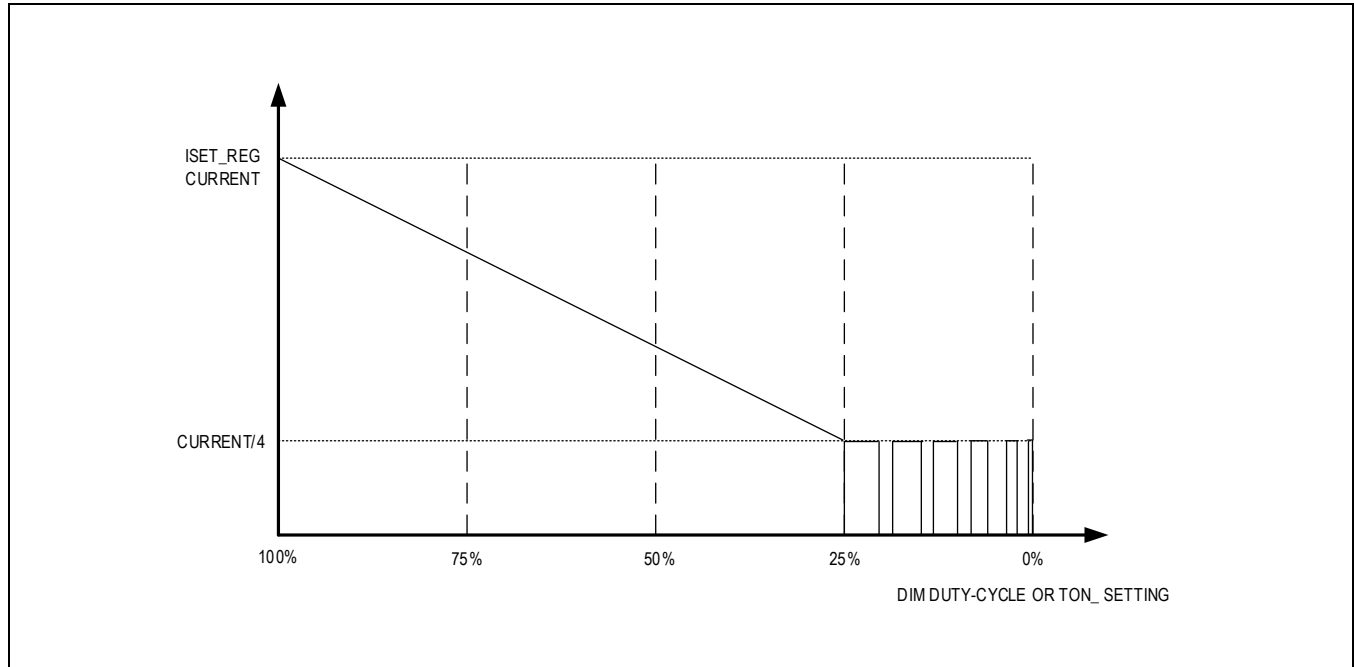


Figure 3. Hybrid Dimming Operation with HDIM[1:0] = 10 (25%)

**Temperature Foldback**

In standalone mode, when an NTC temperature sensor is connected between GND and a resistor (RT1) that is connected to the V18 supply, with a further resistor (RT2) connected from the junction of the NTC and RT1 to the TEMP pin, temperature foldback is implemented. When the temperature reaches the temperature T1 (set by RT1), the current in the LEDs is reduced according to the linear scheme shown in Figure 4. The slope of the current reduction is set by RT2. The MAX25560 is specifically designed to be used with the NTCLE100E3 or a similar NTC device. Table 2 illustrates some examples of values of RT1 and RT2 to obtain certain values of T1 and TDELTA.

**Table 2. Temperature Resistor Values**

| RT1 (kΩ) | RT2 (kΩ) | T1 (°C) | TDELTA (°C) |
|----------|----------|---------|-------------|
| 6.04     | 1.2      | 70      | 30          |
| 6.04     | 2        | 70      | 50          |

When the temperature reaches T1, the OTW bit in register DIAG\_REG is asserted. When the temperature reaches T<sub>OFF</sub>, the LED current is turned off, the bl\_ot bit is set high, and the FLT pin asserts low.

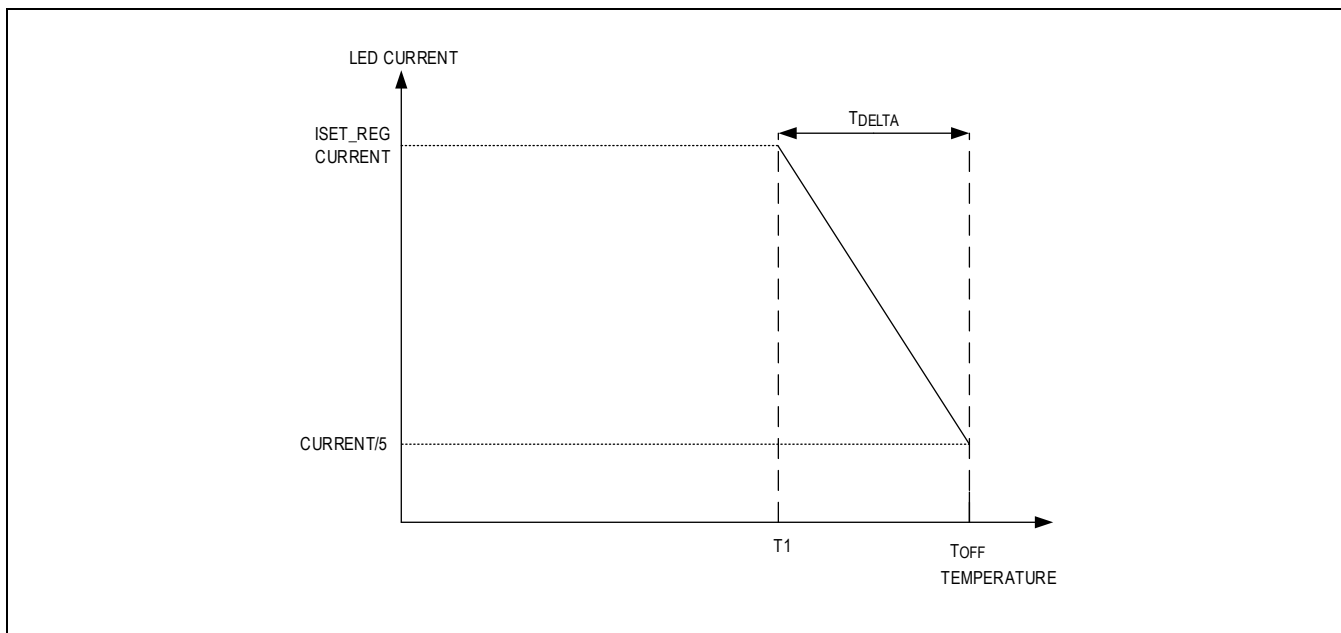


Figure 4. Temperature Foldback Curve

**TEMP External Circuit**

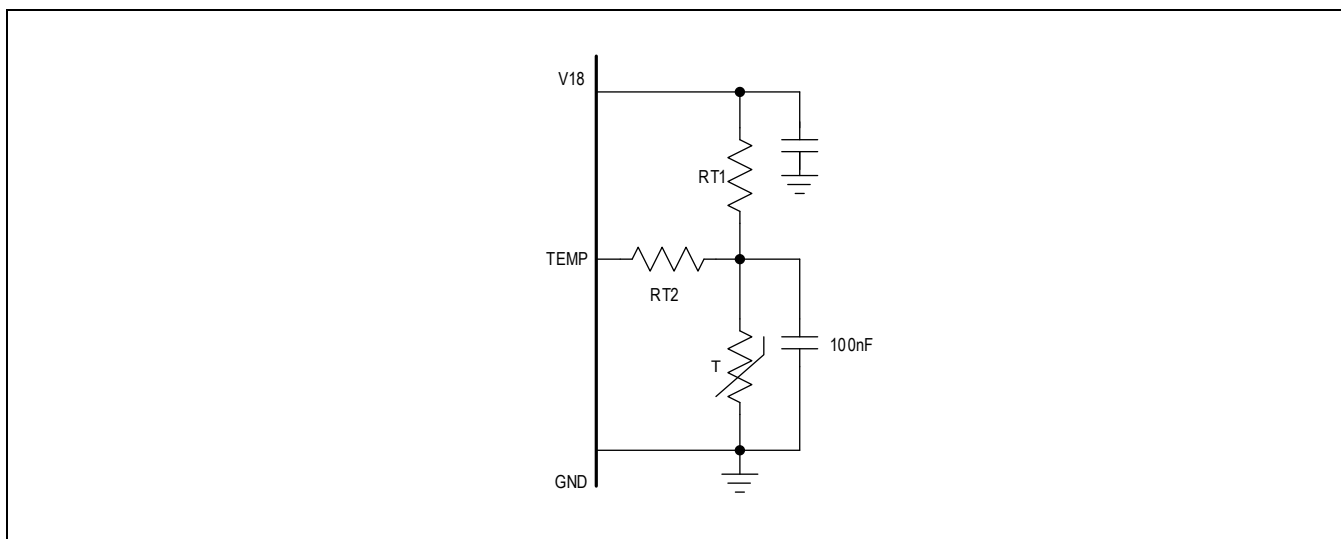


Figure 5. TEMP External Circuit

### Hybrid Dimming Operation Modes

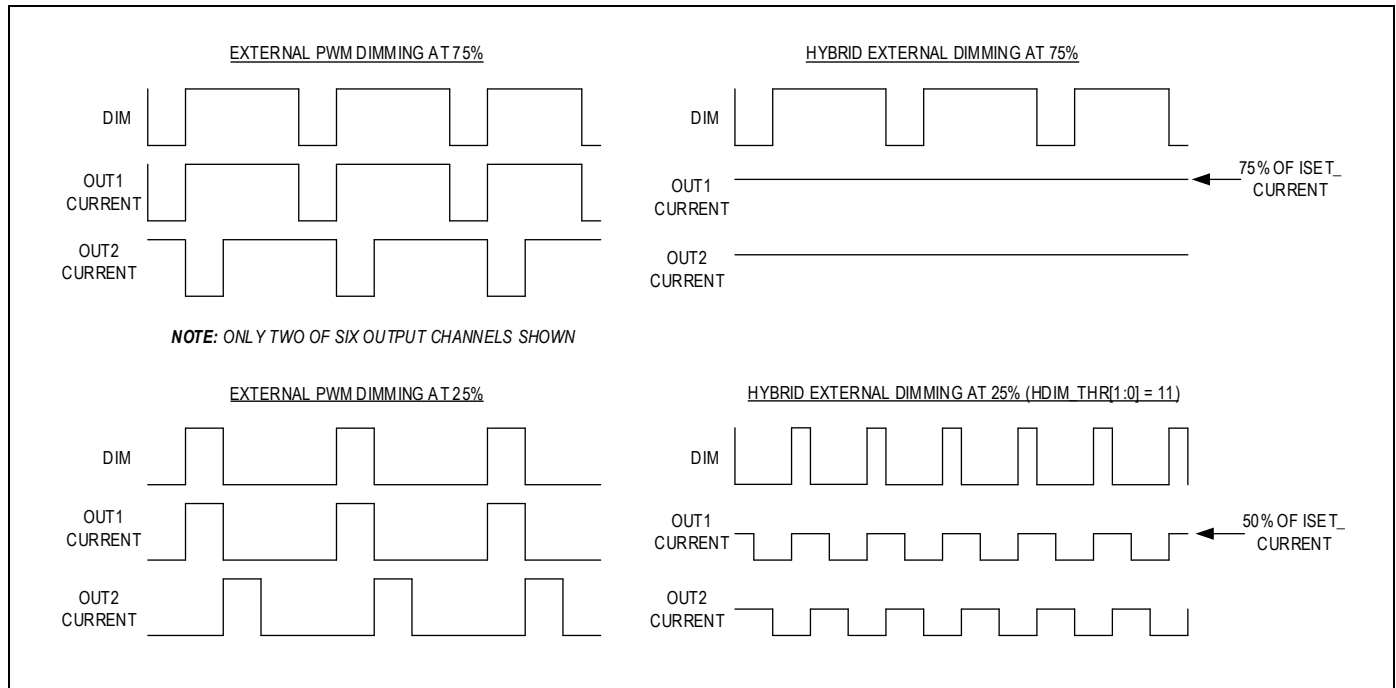


Figure 6. Hybrid Dimming Operation Modes

### MAX25560 Diagnostics and FLT\_B Output

The open-drain fault flag output (FLT\_B) goes low when a fault is detected. Certain faults can be inhibited from causing FLT\_B to go low using the bits in the MASK1 and MASK2 registers.

FLT\_B asserts low for the following faults if not masked (note that not all faults can be masked):

- OUT\_ open, shorted-LED, or short-to-ground
- RT out-of-range, IREF out-of-range, ISET out of range
- Boost undervoltage, V18 out-of-range, V5 out-of-range
- Undervoltage on BATT, boost input overcurrent
- Overtemperature warning

### Open-LED Management and Overvoltage Protection

After the soft-start of the boost converter, the IC detects open-LED strings and disconnects any such strings from the internal minimum OUT\_ voltage detector. This keeps the DC-DC converter output voltage within correct limits and maintains high efficiency. The current in strings that have been detected open is not measured by the ADC and reads as zero.

During normal operation, the DC-DC converter output-regulation loop uses the minimum OUT\_ voltage as the feedback input. If any LED string is open, the voltage at the opened OUT\_ goes to  $V_{LEDGND}$ . The DC-DC converter output voltage then increases to the overvoltage-protection threshold set by the voltage-divider network connected between the converter output, the BSTMON input, and GND. The overvoltage-protection threshold at the DC-DC converter output is determined using the following equation:

Equation 5:

$$V_{OUT_{BSTMON}} = 0.95 \times \left( 1 + \frac{R16}{R17} \right)$$

where 0.95V (typ) is the overvoltage threshold on BSTMON (see the [Functional Diagram](#)). Select  $V_{OUT_{BSTMON}}$  according to the formula below.

$$1.1 \times (V_{LED_{MAX}} + 0.87) < V_{OUT_{BSTMON}} < 2 \times (V_{LED_{MIN}} + 0.55)$$

where:

$V_{LED\_MAX}$  = Maximum expected LED string voltage

$V_{LED\_MIN}$  = Minimum expected LED string voltage

Select R16 and R17 such that the voltage at OUT\_ does not exceed the absolute maximum rating. As soon as the DC-DC converter output reaches the overvoltage-protection threshold, the internal MOSFET is switched off. The overvoltage threshold should be set to less than twice the minimum LED voltage to ensure proper operation and that the BSTMON minimum regulation point of 600mV (typ) is not breached. When an open-LED overvoltage condition occurs, FLTB is latched low.

If all active OUT\_ channels are detected as open the boost converter is disabled. Toggle the EN pin or cycle the power supply to clear an open-LED condition.

### Short-LED Detection

The IC checks for shorted LEDs after the current in any channel is turned on. A shorted-LED is detected at OUT\_ if the following condition is met:

$$V_{OUT\_} > RSDT$$

where RSDT is the programmable short-LED-detection threshold set by the SLDET[1:0] bits in the SETTING\_REG register.

If a short is detected on any of the strings, the affected LED strings are disabled after a delay of one dimming cycle and the FLTB output flag asserts low after two dimming cycles until the device detects that the shorts are removed. Disable short-LED detection by setting SLDET[1:0] to 0x0. Short-LED detection is disabled in low-dimming mode. In external dimming mode with the DIM input connected continuously high, the OUT\_ pins are periodically scanned to detect shorted LEDs. The scan frequency is 100Hz. Similarly, when DIM\_EXT = 0 and internal dimming is being used, shorted LEDs are still detected by periodically scanning the OUT\_ states at 100Hz.

Short-LED detection is also disabled in cases where all active OUT\_ channels rise above 2.5V. This can occur in a boost-converter application when the input voltage becomes higher than the total LED string voltage drop, such as during a battery load dump. If a short-LED fault occurs during a load dump, the fault flag does not assert until the load dump is over and the minimum OUT\_ voltage has fallen below 2.35V. If a load dump occurs after a short LED is detected, the fault flag deasserts until the load dump is over and the minimum OUT\_ voltage has fallen below 2.35V, at which point, the fault flag reasserts.

### LED Short-to-Ground Protection

During startup, a check is performed for OUT\_ pins shorted to ground by sourcing a current of 60μA into the OUT\_ pins. If the pin voltage does not exceed  $V_{OUT\_GND}$ , a short to GND is declared. In this case, the device does not start. Toggle the EN pin or power to clear this condition.

### Thermal Warning/Shutdown

The IC includes thermal protection that operates at a temperature of +160°C. When the thermal-shutdown temperature is reached, the device is immediately disabled so it can cool. When the junction temperature falls by 17°C, the device is re-enabled with the same settings as before (the boost converter performs a soft-start). When a thermal shutdown occurs, the FLTB pin goes low and the OT bit in the DIAG1\_REG register is set to 1.

A thermal warning bit (OTW) is also implemented in the DIAG1\_REG register and indicates that the junction temperature has exceeded 125°C. The OTWMASK bit in the MASK1\_REG register controls whether or not an active OTW bit causes the FLTB pin to go low.

### I<sup>2</sup>C Interface

The MAX25560 features an I<sup>2</sup>C, two-wire serial interface consisting of a serial-data line (SDA) and a serial-clock line (SCL).

SDA and SCL facilitate communication between the device and the controller at clock rates up to 400kHz. The controller, typically a microcontroller, generates SCL and initiates data transfer on the bus. [Figure 1](#) shows the two-wire interface timing diagram.

A controller device communicates with the device by transmitting the correct address followed by the data word. Each transmit sequence is framed by a START (S) or REPEATED START (Sr) condition and a STOP (P) condition. Each word transmitted over the bus is 8 bits long and is always followed by an acknowledge clock pulse.

The SDA line operates as both an input and an open-drain output. A pull-up resistor greater than 500Ω is required on the SDA bus. The SCL line operates as an input only. A pull-up resistor greater than 500Ω is required on SCL if there are multiple controllers on the bus, or if the controller in a single-controller system has an open-drain SCL output. Series resistors in line with SDA and SCL are optional. The SCL and SDA inputs suppress noise spikes to assure proper device operation, even on a noisy bus.

### Bit Transfer

One data bit is transferred during each SCL cycle. The data on SDA must remain stable during the high period of the SCL pulse. Changes in SDA while SCL is high are control signals (see the [STOP and START Conditions](#) section). SDA and SCL idle high when the I<sup>2</sup>C bus is not busy.

### STOP and START Conditions

A controller device initiates communication by issuing a START condition. A START condition is a high-to-low transition on SDA with SCL high. A STOP condition is a low-to-high transition on SDA while SCL is high ([Figure 7](#)). A START (S) condition from the controller signals the beginning of a transmission to the device. The controller terminates transmission and frees the bus by issuing a STOP (P) condition. The bus remains active if a REPEATED START (Sr) condition is generated instead of a STOP condition.

### Early STOP Condition

The MAX25560 recognizes a STOP condition at any point during data transmission except if the STOP condition occurs in the same high pulse as a START condition.

### Clock Stretching

In general, the clock signal generation for the I<sup>2</sup>C bus is the responsibility of the controller device. The I<sup>2</sup>C specification allows slow target devices to alter the clock signal by holding down the clock line, a process that is typically called clock stretching. The MAX25560 does not use clock stretching to hold down the clock line.

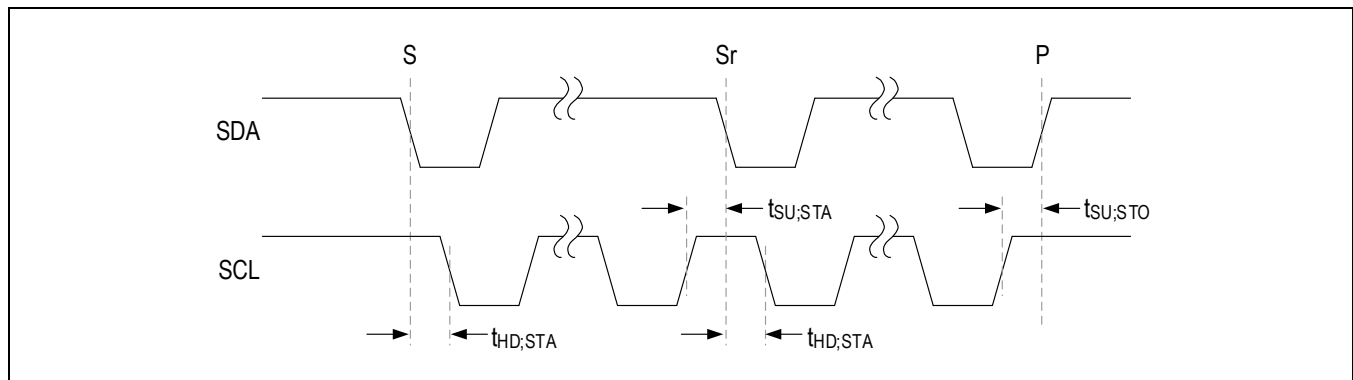


Figure 7. START, STOP, and REPEATED START Conditions

### I<sup>2</sup>C General Call Address

The IC does not implement the I<sup>2</sup>C specification's general call address. The device will not issue an acknowledge to the general call address (0b0000\_0000).

### Acknowledge

The acknowledge bit (ACK) is a clocked ninth bit that the device uses to handshake receipt of each byte of data. The device pulls down SDA during the controller-generated ninth clock pulse. The SDA line must remain stable and low during the high period of the acknowledge clock pulse. Monitoring ACK allows for detection of unsuccessful data transfers. An unsuccessful data transfer occurs if a receiving device is busy or if a system fault has occurred. In the event of an unsuccessful data transfer, the bus controller can reattempt communication.

**Target Address**

The I<sup>2</sup>C addresses are shown in [Table 3](#).

**Table 3. I<sup>2</sup>C Addresses**

| ADD PIN CONNECTION | 7-BIT ADDRESS | 8-BIT READ ADDRESS | 8-BIT WRITE ADDRESS |
|--------------------|---------------|--------------------|---------------------|
| GND                | 0x23          | 0x47               | 0x46                |
| V18                | 0x2B          | 0x57               | 0x56                |

The address is defined as the 7 most significant bits (MSBs) followed by the R/W bit. Set the R/W bit to 1 to configure the device to read mode. Set the R/W bit to 0 to configure the device to write mode. The address is the first byte of information sent to the device after the START condition.

**Write-Data Format**

A write to the device includes transmission of a START condition, the target address with the R/W bit set to 0, one byte of data to register address, one to eight bytes of data to write to registers, and a STOP condition. [Figure 8](#) illustrates the proper format for one frame. If multiple bytes are transmitted, they are written to sequential registers starting at the register address transmitted. If the register address for the write reaches the end of the valid address space, the target register pointer will stay at the last valid register. If the write starts out-of-bounds, then all the bytes written will be discarded and the IC will return a NACK for each byte transmitted.

**MAX25560 Read-Data Format**

A read from the device includes the following:

- Transmission of a START condition
- Target address with the R/W bit set to 0
- 1 byte of data to register address
- Restart condition
- Target address with R/W bit set to 1
- 1-8 bytes written by the IC
- STOP condition

[Figure 8](#) illustrates the correct frame format. The controller device must acknowledge each byte received, and provide a NACK at the last byte read.

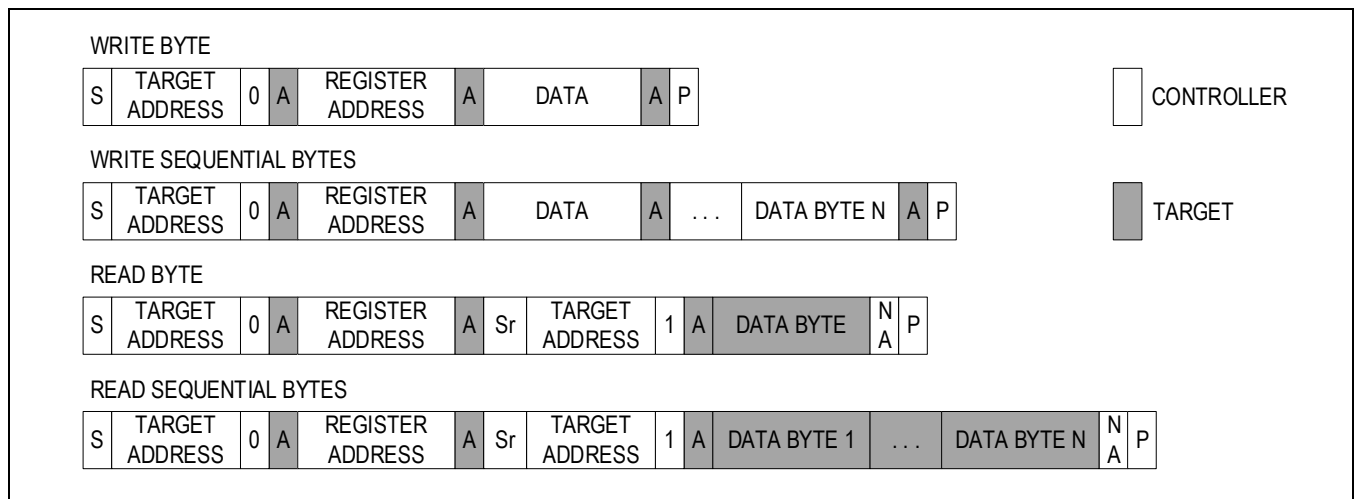


Figure 8. Figure 9. Data Format of I<sup>2</sup>C Interface



## Register Map

MAX25560

| ADDRESS               | NAME                               | MSB          |               |              |                 |              |             |                   | LSB  |
|-----------------------|------------------------------------|--------------|---------------|--------------|-----------------|--------------|-------------|-------------------|------|
| <b>USER_REGISTERS</b> |                                    |              |               |              |                 |              |             |                   |      |
| 0x00                  | <a href="#">DEV_ID_REG[7:0]</a>    | DEV_ID[7:0]  |               |              |                 |              |             |                   |      |
| 0x01                  | <a href="#">REV_ID_REG[7:0]</a>    | -            | -             | -            | -               | REV_ID[3:0]  |             |                   |      |
| 0x02                  | <a href="#">SET_REG[7:0]</a>       | -            | -             | -            | BL_ILIM         | BSTFORCE     | FAST_S<br>S | ENA               | PSEN |
| 0x03                  | <a href="#">IMODE_REG[7:0]</a>     | -            | -             | -            | DIS_ISNS_S<br>D | DIM_EXT      | HDIM        | HDIM_THR_1_0[1:0] |      |
| 0x04                  | <a href="#">ISET_REG[7:0]</a>      | -            | iset[6:0]     |              |                 |              |             |                   |      |
| 0x05                  | <a href="#">TON1H_REG[7:0]</a>     | TON1H[7:0]   |               |              |                 |              |             |                   |      |
| 0x06                  | <a href="#">TON1L_REG[7:0]</a>     | TON1L[7:0]   |               |              |                 |              |             |                   |      |
| 0x07                  | <a href="#">TON2H_REG[7:0]</a>     | TON2H[7:0]   |               |              |                 |              |             |                   |      |
| 0x08                  | <a href="#">TON2L_REG[7:0]</a>     | TON2L[7:0]   |               |              |                 |              |             |                   |      |
| 0x09                  | <a href="#">TON3H_REG[7:0]</a>     | TON3H[7:0]   |               |              |                 |              |             |                   |      |
| 0x0A                  | <a href="#">TON3L_REG[7:0]</a>     | TON3L[7:0]   |               |              |                 |              |             |                   |      |
| 0x0B                  | <a href="#">TON4H_REG[7:0]</a>     | TON4H[7:0]   |               |              |                 |              |             |                   |      |
| 0x0C                  | <a href="#">TON4L_REG[7:0]</a>     | TON4L[7:0]   |               |              |                 |              |             |                   |      |
| 0x0D                  | <a href="#">TON1_4LSB_REG[7:0]</a> | TON4LSB[1:0] |               | TON3LSB[1:0] |                 | TON2LSB[1:0] |             | TON1LSB[1:0]      |      |
| 0x0E                  | <a href="#">TON5H_REG[7:0]</a>     | TON5H[7:0]   |               |              |                 |              |             |                   |      |
| 0x0F                  | <a href="#">TON5L_REG[7:0]</a>     | TON5L[7:0]   |               |              |                 |              |             |                   |      |
| 0x10                  | <a href="#">TON6H_REG[7:0]</a>     | TON6H[7:0]   |               |              |                 |              |             |                   |      |
| 0x11                  | <a href="#">TON6L_REG[7:0]</a>     | TON6L[7:0]   |               |              |                 |              |             |                   |      |
| 0x12                  | <a href="#">TON5_6LSB_REG[7:0]</a> | -            | -             | -            | TON_ALL         | TON6LSB[1:0] |             | TON5LSB[1:0]      |      |
| 0x13                  | <a href="#">SETTING_REG[7:0]</a>   | -            | FPWM[2:0]     |              |                 | SS_OFF       | SSL         | SLDET[1:0]        |      |
| 0x14                  | <a href="#">DISABLE_REG[7:0]</a>   | -            | SLDET_DI<br>S | CP_DIS       | DIS6            | DIS5         | DIS4        | DIS3              | DIS2 |

| ADDRESS | NAME                                 | MSB              |         |             |           |             |           |                 | LSB     |
|---------|--------------------------------------|------------------|---------|-------------|-----------|-------------|-----------|-----------------|---------|
| 0x15    | <a href="#">FADING_REG[7:0]</a>      | -                | -       | -           | FADE_GAIN | FADE_IN_OUT | TDIM[2:0] |                 |         |
| 0x16    | <a href="#">LO_DIM[7:0]</a>          | -                | -       | LO_DIM6     | LO_DIM5   | LO_DIM4     | LO_DIM3   | LO_DIM2         | LO_DIM1 |
| 0x17    | <a href="#">OPEN_REG[7:0]</a>        | -                | -       | OUT6O       | OUT5O     | OUT4O       | OUT3O     | OUT2O           | OUT1O   |
| 0x18    | <a href="#">SHORTGND_REG[7:0]</a>    | -                | -       | OUT6SG      | OUT5SG    | OUT4SG      | OUT3SG    | OUT2SG          | OUT1SG  |
| 0x19    | <a href="#">SHORTED_LED_REG[7:0]</a> | -                | -       | OUT6SL      | OUT5SL    | OUT4SL      | OUT3SL    | OUT2SL          | OUT1SL  |
| 0x1A    | <a href="#">MASK1_REG[7:0]</a>       | -                | -       | -           | BSTUVMASK | OMASK       | SGMASK    | OTWMASK         | SLMASK  |
| 0x1B    | <a href="#">MASK2_REG[7:0]</a>       | -                | -       | BATT_UVMASK | -         | -           | -         | -               | -       |
| 0x1C    | <a href="#">DIAG1_REG[7:0]</a>       | RTOOR            | ISETOOR | IREFOOR     | BSTUV     | BSTOV       | HW_RST    | OTW             | OT      |
| 0x1D    | <a href="#">DIAG2_REG[7:0]</a>       | V18OOR           | -       | BATT_UV     | -         | V5OOR       | -         | -               | ISNS_SD |
| 0x29    | <a href="#">DIM_TON_HI[7:0]</a>      | dim_ton_hi[7:0]  |         |             |           |             |           |                 |         |
| 0x2A    | <a href="#">DIM_TON_MID[7:0]</a>     | dim_ton_mid[7:0] |         |             |           |             |           |                 |         |
| 0x2B    | <a href="#">DIM_TON_LO[7:0]</a>      | -                | -       | -           | -         | -           | -         | dim_ton_lo[1:0] |         |
| 0x2C    | <a href="#">DIM_F_HI[7:0]</a>        | dim_f_hi[7:0]    |         |             |           |             |           |                 |         |
| 0x2D    | <a href="#">DIM_F_MID[7:0]</a>       | dim_f_mid[7:0]   |         |             |           |             |           |                 |         |
| 0x2E    | <a href="#">DIM_F_LO[7:0]</a>        | -                | -       | -           | -         | -           | -         | dim_f_lo[1:0]   |         |

## Register Details

### [DEV\\_ID\\_REG \(0x0\)](#)

| BIT   | 7           | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------|-------------|---|---|---|---|---|---|---|
| Field | DEV_ID[7:0] |   |   |   |   |   |   |   |
| Reset |             |   |   |   |   |   |   |   |

|             |           |
|-------------|-----------|
| Access Type | Read Only |
|-------------|-----------|

| BITFIELD | BITS | DESCRIPTION   |
|----------|------|---|
| DEV_ID   | 7:0  | Device ID <i>{Variable not found in the variables list}</i> |

**REV\_ID\_REG (0x1)**

| BIT         | 7 | 6 | 5 | 4 | 3           | 2 | 1 | 0 |
|-------------|---|---|---|---|-------------|---|---|---|
| Field       | – | – | – | – | REV_ID[3:0] |   |   |   |
| Reset       | – | – | – | – | 0x1         |   |   |   |
| Access Type | – | – | – | – | Read Only   |   |   |   |

| BITFIELD | BITS | DESCRIPTION         |
|----------|------|---------------------|
| REV_ID   | 3:0  | Device revision ID. |

**SET\_REG (0x2)**

| BIT         | 7 | 6 | 5 | 4           | 3           | 2           | 1           | 0           |
|-------------|---|---|---|-------------|-------------|-------------|-------------|-------------|
| Field       | – | – | – | BL_ILIM     | BSTFORCE    | FAST_SS     | ENA         | PSEN        |
| Reset       | – | – | – | 0b0         | 0b0         | 0b0         | 0b0         | 0b0         |
| Access Type | – | – | – | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read |

| BITFIELD | BITS | DESCRIPTION  | DECODE  |
|----------|------|--|---|
| BL_ILIM  | 4    | Sets boost current limit to one of two levels. When 0, the higher current limit is selected.             | 0x0: Current limit set high<br>0x1: Current limit set low |
| BSTFORCE | 3    | When 1, this bit forces the boost converter to run continuously and independently of the dimming signal. |   |
| FAST_SS  | 2    | Selects slow or fast boost soft-start. Set to 1 for fast soft-start.                                     |   |
| ENA      | 1    | Boost converter and LED outputs enable bit. Set to 1 to enable the device.                               |   |
| PSEN     | 0    | When 0, phase shifting is disabled. When 1, phase shifting is enabled.                                   |   |

**IMODE\_REG (0x3)**

| BIT         | 7 | 6 | 5 | 4           | 3           | 2           | 1                 | 0 |
|-------------|---|---|---|-------------|-------------|-------------|-------------------|---|
| Field       | – | – | – | DIS_ISNS_SD | DIM_EXT     | HDIM        | HDIM_THR_1_0[1:0] |   |
| Reset       | – | – | – | 0x0         | 0b1         | 0b0         | 0b00              |   |
| Access Type | – | – | – | Write, Read | Write, Read | Write, Read | Write, Read       |   |

| BITFIELD     | BITS | DESCRIPTION   |       |
|--------------|------|---|-------|
| DIS_ISNS_SD  | 4    | When 1, this bit disables the input overcurrent shutdown function. When an overcurrent is detected, the ISNS_SD bit is asserted, but the device continues operation and FLTB does not assert low. |       |
| DIM_EXT      | 3    | When 1, dimming through the DIM pin is enabled. When 0, dimming is controlled using the TON__ registers.  |       |
| HDIM         | 2    | When 1, hybrid dimming is enabled.  |       |
| HDIM_THR_1_0 | 1:0  | Set hybrid dimming threshold.   |       |
|              |      | 00  | 6.25% |
|              |      | 10  | 12.5% |
|              |      | 10  | 25%   |
|              |      | 11  | 50%   |

**ISET\_REG (0x4)**

| BIT         | 7 | 6           | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|---|-------------|---|---|---|---|---|---|
| Field       | – | iset[6:0]   |   |   |   |   |   |   |
| Reset       | – | 0b0001000   |   |   |   |   |   |   |
| Access Type | – | Write, Read |   |   |   |   |   |   |

| BITFIELD | BITS | DESCRIPTION   | DECODE  |
|----------|------|---|---|
| iset     | 6:0  | The value in this register sets the OUT_LED current in the range 93mA to 220mA. | 0x00: 34.5mA<br>0x01: 36mA<br>...<br>0x2B: 99mA<br>0x2C: 100.5mA<br>0x2D: 102mA<br>...<br>0x7D: 222mA<br>0x7E: 223.5mA<br>0x7F: 225mA |

**TON1H REG (0x5)**

On-time setting for channel 1 with 50ns resolution, high byte.

| BIT         | 7           | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|---|---|---|---|---|---|---|
| Field       | TON1H[7:0]  |   |   |   |   |   |   |   |
| Reset       | 0xFF        |   |   |   |   |   |   |   |
| Access Type | Write, Read |   |   |   |   |   |   |   |

| BITFIELD | BITS | DESCRIPTION                                    |
|----------|------|--|
| TON1H    | 7:0  | High byte of 18-bit TON setting for channel 1. |

**TON1L REG (0x6)**

On-time setting for channel 1 with 50ns resolution, middle byte.

| BIT         | 7           | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|---|---|---|---|---|---|---|
| Field       | TON1L[7:0]  |   |   |   |   |   |   |   |
| Reset       | 0xFF        |   |   |   |   |   |   |   |
| Access Type | Write, Read |   |   |   |   |   |   |   |

| BITFIELD | BITS | DESCRIPTION                                      |
|----------|------|--|
| TON1L    | 7:0  | Middle byte of 18-bit TON setting for channel 1. |

**TON2H REG (0x7)**

On-time setting for channel 2 with 50ns resolution, high byte.

| BIT         | 7           | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|---|---|---|---|---|---|---|
| Field       | TON2H[7:0]  |   |   |   |   |   |   |   |
| Reset       | 0xFF        |   |   |   |   |   |   |   |
| Access Type | Write, Read |   |   |   |   |   |   |   |

| BITFIELD | BITS | DESCRIPTION                                    |
|----------|------|--|
| TON2H    | 7:0  | High byte of 18-bit TON setting for channel 2. |

**TON2L REG (0x8)**

On-time setting for channel 2 with 50ns resolution, middle byte.

| BIT         | 7           | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|---|---|---|---|---|---|---|
| Field       | TON2L[7:0]  |   |   |   |   |   |   |   |
| Reset       | 0xFF        |   |   |   |   |   |   |   |
| Access Type | Write, Read |   |   |   |   |   |   |   |

| BITFIELD | BITS | DESCRIPTION                                      |
|----------|------|--|
| TON2L    | 7:0  | Middle byte of 18-bit TON setting for channel 2. |

**TON3H REG (0x9)**

On-time setting for channel 3 with 50ns resolution, high byte.

| BIT         | 7           | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|---|---|---|---|---|---|---|
| Field       | TON3H[7:0]  |   |   |   |   |   |   |   |
| Reset       | 0xFF        |   |   |   |   |   |   |   |
| Access Type | Write, Read |   |   |   |   |   |   |   |

| BITFIELD | BITS | DESCRIPTION                                    |
|----------|------|--|
| TON3H    | 7:0  | High byte of 18-bit TON setting for channel 3. |

**TON3L REG (0xA)**

On-time setting for channel 3 with 50ns resolution, middle byte.

| BIT         | 7           | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|---|---|---|---|---|---|---|
| Field       | TON3L[7:0]  |   |   |   |   |   |   |   |
| Reset       | 0xFF        |   |   |   |   |   |   |   |
| Access Type | Write, Read |   |   |   |   |   |   |   |

| BITFIELD | BITS | DESCRIPTION                                      |
|----------|------|--|
| TON3L    | 7:0  | Middle byte of 18-bit TON setting for channel 3. |

**TON4H REG (0xB)**

On-time setting for channel 4 with 50ns resolution, high byte.

| BIT         | 7           | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|---|---|---|---|---|---|---|
| Field       | TON4H[7:0]  |   |   |   |   |   |   |   |
| Reset       | 0xFF        |   |   |   |   |   |   |   |
| Access Type | Write, Read |   |   |   |   |   |   |   |

| BITFIELD | BITS | DESCRIPTION                                    |
|----------|------|--|
| TON4H    | 7:0  | High byte of 18-bit TON setting for channel 4. |

**TON4L REG (0xC)**

On-time setting for channel 4 with 50ns resolution, middle byte.

| BIT         | 7           | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|---|---|---|---|---|---|---|
| Field       | TON4L[7:0]  |   |   |   |   |   |   |   |
| Reset       | 0xFF        |   |   |   |   |   |   |   |
| Access Type | Write, Read |   |   |   |   |   |   |   |

| BITFIELD | BITS | DESCRIPTION                                      |
|----------|------|--|
| TON4L    | 7:0  | Middle byte of 18-bit TON setting for channel 4. |

**TON1\_4LSB REG (0xD)**

LSBs of on-time setting for all channels with 50ns resolution.

| BIT         | 7            | 6 | 5            | 4 | 3            | 2 | 1            | 0 |
|-------------|--------------|---|--------------|---|--------------|---|--------------|---|
| Field       | TON4LSB[1:0] |   | TON3LSB[1:0] |   | TON2LSB[1:0] |   | TON1LSB[1:0] |   |
| Reset       | 0b11         |   | 0b11         |   | 0b11         |   | 0b11         |   |
| Access Type | Write, Read  |   | Write, Read  |   | Write, Read  |   | Write, Read  |   |

| BITFIELD | BITS | DESCRIPTION   |
|----------|------|---|
| TON4LSB  | 7:6  | 2 least significant bits of 18-bit TON setting for channel 4. |
| TON3LSB  | 5:4  | 2 least significant bits of 18-bit TON setting for channel 3. |

| BITFIELD | BITS | DESCRIPTION   |
|----------|------|---|
| TON2LSB  | 3:2  | 2 least significant bits of 18-bit TON setting for channel 2. |
| TON1LSB  | 1:0  | 2 least significant bits of 18-bit TON setting for channel 1. |

**TON5H\_REG (0xE)**

| BIT         | 7           | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|---|---|---|---|---|---|---|
| Field       | TON5H[7:0]  |   |   |   |   |   |   |   |
| Reset       | 0xFF        |   |   |   |   |   |   |   |
| Access Type | Write, Read |   |   |   |   |   |   |   |

| BITFIELD | BITS | DESCRIPTION                                    |
|----------|------|--|
| TON5H    | 7:0  | High byte of 18-bit TON setting for channel 5. |

**TON5L\_REG (0xF)**

| BIT         | 7           | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|---|---|---|---|---|---|---|
| Field       | TON5L[7:0]  |   |   |   |   |   |   |   |
| Reset       | 0xFF        |   |   |   |   |   |   |   |
| Access Type | Write, Read |   |   |   |   |   |   |   |

| BITFIELD | BITS | DESCRIPTION                                      |
|----------|------|--|
| TON5L    | 7:0  | Middle byte of 18-bit TON setting for channel 5. |

**TON6H\_REG (0x10)**

| BIT         | 7           | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|---|---|---|---|---|---|---|
| Field       | TON6H[7:0]  |   |   |   |   |   |   |   |
| Reset       | 0xFF        |   |   |   |   |   |   |   |
| Access Type | Write, Read |   |   |   |   |   |   |   |



| BITFIELD | BITS | DESCRIPTION                                    |
|----------|------|--|
| TON6H    | 7:0  | High byte of 18-bit TON setting for channel 6. |

**TON6L\_REG (0x11)**

| BIT         | 7           | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|---|---|---|---|---|---|---|
| Field       | TON6L[7:0]  |   |   |   |   |   |   |   |
| Reset       | 0xFF        |   |   |   |   |   |   |   |
| Access Type | Write, Read |   |   |   |   |   |   |   |

| BITFIELD | BITS | DESCRIPTION                                      |
|----------|------|--|
| TON6L    | 7:0  | Middle byte of 18-bit TON setting for channel 6. |

**TON5\_6LSB\_REG (0x12)**

| BIT         | 7 | 6 | 5 | 4           | 3            | 2 | 1            | 0 |
|-------------|---|---|---|-------------|--------------|---|--------------|---|
| Field       | – | – | – | TON_ALL     | TON6LSB[1:0] |   | TON5LSB[1:0] |   |
| Reset       | – | – | – | 0b0         | 0b11         |   | 0b11         |   |
| Access Type | – | – | – | Write, Read | Write, Read  |   | Write, Read  |   |

| BITFIELD | BITS | DESCRIPTION  |
|----------|------|--|
| TON_ALL  | 4    | When 1, this bit causes the TON1 value to be used for all active channels. |
| TON6LSB  | 3:2  | 2 least significant bits of 18-bit TON setting for channel 6.              |
| TON5LSB  | 1:0  | 2 least significant bits of 18-bit TON setting for channel 5.              |

**SETTING\_REG (0x13)**

| BIT         | 7 | 6           | 5 | 4 | 3           | 2           | 1           | 0 |
|-------------|---|-------------|---|---|-------------|-------------|-------------|---|
| Field       | – | FPWM[2:0]   |   |   | SS_OFF      | SSL         | SLDET[1:0]  |   |
| Reset       | – | 0b001       |   |   | 0b0         | 0b0         | 0b00        |   |
| Access Type | – | Write, Read |   |   | Write, Read | Write, Read | Write, Read |   |

| BITFIELD | BITS | DESCRIPTION  |       |       |                    |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|----------|------|--|-------|-------|--------------------|--------------------|----|----|----|-----|---|---|---|-----|---|---|---|-----|---|---|---|-----|---|---|---|-----|---|---|---|------|---|---|---|------|---|---|---|------|
| FPWM     | 6:4  | These bits set the PWM frequency in internal PWM mode.   |       |       |                    |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      | <table border="1"> <thead> <tr> <th>FPWM2</th> <th>FPWM1</th> <th>FPWM0</th> <th>PWM FREQUENCY (Hz)</th> </tr> </thead> <tbody> <tr> <td>0</td> <td>0</td> <td>0</td> <td>153</td> </tr> <tr> <td>0</td> <td>0</td> <td>1</td> <td>203</td> </tr> <tr> <td>0</td> <td>1</td> <td>0</td> <td>305</td> </tr> <tr> <td>0</td> <td>1</td> <td>1</td> <td>610</td> </tr> <tr> <td>1</td> <td>0</td> <td>0</td> <td>980</td> </tr> <tr> <td>1</td> <td>0</td> <td>1</td> <td>1220</td> </tr> <tr> <td>1</td> <td>1</td> <td>0</td> <td>1401</td> </tr> <tr> <td>1</td> <td>1</td> <td>1</td> <td>1634</td> </tr> </tbody> </table> | FPWM2 | FPWM1 | FPWM0              | PWM FREQUENCY (Hz) | 0  | 0  | 0  | 153 | 0 | 0 | 1 | 203 | 0 | 1 | 0 | 305 | 0 | 1 | 1 | 610 | 1 | 0 | 0 | 980 | 1 | 0 | 1 | 1220 | 1 | 1 | 0 | 1401 | 1 | 1 | 1 | 1634 |
|          |      | FPWM2  | FPWM1 | FPWM0 | PWM FREQUENCY (Hz) |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      | 0  | 0     | 0     | 153                |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      | 0  | 0     | 1     | 203                |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      | 0  | 1     | 0     | 305                |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      | 0  | 1     | 1     | 610                |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      | 1  | 0     | 0     | 980                |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      | 1  | 0     | 1     | 1220               |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      | 1  | 1     | 0     | 1401               |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
| 1        | 1    | 1  | 1634  |       |                    |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
| SS_OFF   | 3    | When 1, spread-spectrum switching is disabled. Default value is 0.   |       |       |                    |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
| SSL      | 2    | When spread spectrum is enabled, the SSL bit sets the level of spread. When 0, the spread is nominally $\pm 6\%$ . When 1, the spread is $\pm 3\%$ . When changing the percentage, disable spread spectrum using the SS_OFF bit first. Then, change the value of SSL. Finally, reenables spread spectrum using SS_OFF.   |       |       |                    |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
| SLDET    | 1:0  | Shorted-LED threshold Settings.  |       |       |                    |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      | <table border="1"> <tbody> <tr> <td>00</td> <td>8V</td> </tr> <tr> <td>01</td> <td>3V</td> </tr> <tr> <td>10</td> <td>6V</td> </tr> <tr> <td>11</td> <td>8V</td> </tr> </tbody> </table>   | 00    | 8V    | 01                 | 3V                 | 10 | 6V | 11 | 8V  |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      | 00   | 8V    |       |                    |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      | 01   | 3V    |       |                    |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      | 10   | 6V    |       |                    |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
| 11       | 8V   |  |       |       |                    |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      |  |       |       |                    |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      |  |       |       |                    |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |
|          |      |  |       |       |                    |                    |    |    |    |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |     |   |   |   |      |   |   |   |      |   |   |   |      |

**DISABLE REG (0x14)**

Channel-disable bits.

| BIT         | 7 | 6           | 5           | 4           | 3           | 2           | 1           | 0           |
|-------------|---|-------------|-------------|-------------|-------------|-------------|-------------|-------------|
| Field       | – | SLDET_DIS   | CP_DIS      | DIS6        | DIS5        | DIS4        | DIS3        | DIS2        |
| Reset       | – | 0x0         | 0b0         | 0b0         | 0b0         | 0b0         | 0b0         | 0b0         |
| Access Type | – | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read |

| BITFIELD  | BITS | DESCRIPTION  |
|-----------|------|--|
| SLDET_DIS | 6    | When 1 the shorted-LED detection is disabled.  |
| CP_DIS    | 5    | When 1, this bit disables the internal charge pump which drives the NGATE pin. Set to 1 when an external series switch is not used. Setting CP_DIS to zero during operation will cause complete shutdown of the device and is not recommended. |
| DIS6      | 4    | Set bit to 1 to disable OUT6. This must be done before ENA is written to 1.  |
| DIS5      | 3    | Set bit to 1 to disable OUT5. This must be done before ENA is written to 1.  |
| DIS4      | 2    | Set bit to 1 to disable OUT4. This must be done before ENA is written to 1.  |
| DIS3      | 1    | Set bit to 1 to disable OUT3. This must be done before ENA is written to 1.  |
| DIS2      | 0    | Set bit to 1 to disable OUT2. This must be done before ENA is written to 1.  |

**FADING REG (0x15)**

| BIT         | 7 | 6 | 5 | 4           | 3           | 2           | 1 | 0 |
|-------------|---|---|---|-------------|-------------|-------------|---|---|
| Field       | – | – | – | FADE_GAIN   | FADE_IN_OUT | TDIM[2:0]   |   |   |
| Reset       | – | – | – | 0b0         | 0b0         | 0b000       |   |   |
| Access Type | – | – | – | Write, Read | Write, Read | Write, Read |   |   |

| BITFIELD    | BITS | DESCRIPTION  | DECODE   |
|-------------|------|--|--|
| FADE_GAIN   | 4    | When this bit is set to 1, the fade-in-out function has a gain of 12.5%, otherwise 6.25%.  |  |
| FADE_IN_OUT | 3    | When this bit is set to 1, the fade-in-out function for the LED dimming is enabled.  |  |
| TDIM        | 2:0  | Sets the fading update time interval according to $2^{TDIM}$ . TDIM can be between 0 and 5. When set to 0, fading is updated on every dimming cycle. | 0x0: 1<br>0x1: 2<br>0x2: 4<br>0x3: 8<br>0x4: 16<br>0x5: 32<br>0x6: N/A<br>0x7: N/A |

**LO\_DIM (0x16)**

| BIT   | 7 | 6 | 5       | 4       | 3       | 2       | 1       | 0       |
|-------|---|---|---------|---------|---------|---------|---------|---------|
| Field | – | – | LO_DIM6 | LO_DIM5 | LO_DIM4 | LO_DIM3 | LO_DIM2 | LO_DIM1 |
| Reset | – | – | 0b0     | 0b0     | 0b0     | 0b0     | 0b0     | 0b0     |

|                    |   |   |           |           |           |           |           |           |
|--------------------|---|---|-----------|-----------|-----------|-----------|-----------|-----------|
| <b>Access Type</b> | – | – | Read Only | Read Only | Read Only | Read Only | Read Only | Read Only |
|--------------------|---|---|-----------|-----------|-----------|-----------|-----------|-----------|

| BITFIELD | BITS | DESCRIPTION                                     |
|----------|------|---|
| LO_DIM6  | 5    | When 1, indicates channel 6 is in low-dim mode. |
| LO_DIM5  | 4    | When 1, indicates channel 5 is in low-dim mode. |
| LO_DIM4  | 3    | When 1, indicates channel 4 is in low-dim mode. |
| LO_DIM3  | 2    | When 1, indicates channel 3 is in low-dim mode. |
| LO_DIM2  | 1    | When 1, indicates channel 2 is in low-dim mode. |
| LO_DIM1  | 0    | When 1, indicates channel 1 is in low-dim mode. |

### OPEN REG (0x17)

Open-string diagnostics.

| BIT                | 7 | 6 | 5                  | 4                  | 3                  | 2                  | 1                  | 0                  |
|--------------------|---|---|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|
| <b>Field</b>       | – | – | OUT6O              | OUT5O              | OUT4O              | OUT3O              | OUT2O              | OUT1O              |
| <b>Reset</b>       | – | – | 0b0                | 0b0                | 0b0                | 0b0                | 0b0                | 0b0                |
| <b>Access Type</b> | – | – | Read Clears<br>All | Read Clears<br>All | Read Clears<br>All | Read Clears<br>All | Read Clears<br>All | Read Clears<br>All |

| BITFIELD | BITS | DESCRIPTION                             |
|----------|------|---|
| OUT6O    | 5    | If 1, an open is detected on channel 6. |
| OUT5O    | 4    | If 1, an open is detected on channel 5. |
| OUT4O    | 3    | If 1, an open is detected on channel 4. |
| OUT3O    | 2    | If 1, an open is detected on channel 3. |
| OUT2O    | 1    | If 1, an open is detected on channel 2. |
| OUT1O    | 0    | If 1, an open is detected on channel 1. |

### SHORTGND REG (0x18)

Short-to-ground diagnostics.

| BIT          | 7 | 6 | 5      | 4      | 3      | 2      | 1      | 0      |
|--------------|---|---|--------|--------|--------|--------|--------|--------|
| <b>Field</b> | – | – | OUT6SG | OUT5SG | OUT4SG | OUT3SG | OUT2SG | OUT1SG |

|                    |   |   |                    |                    |                    |                    |                    |                    |
|--------------------|---|---|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|
| <b>Reset</b>       | – | – | 0b0                | 0b0                | 0b0                | 0b0                | 0b0                | 0b0                |
| <b>Access Type</b> | – | – | Read Clears<br>All | Read Clears<br>All | Read Clears<br>All | Read Clears<br>All | Read Clears<br>All | Read Clears<br>All |

| BITFIELD | BITS | DESCRIPTION  |
|----------|------|--|
| OUT6SG   | 5    | If 1, a short-to-ground is detected on channel 6 at startup. |
| OUT5SG   | 4    | If 1, a short-to-ground is detected on channel 5 at startup. |
| OUT4SG   | 3    | If 1, a short-to-ground is detected on channel 4 at startup. |
| OUT3SG   | 2    | If 1, a short-to-ground is detected on channel 3 at startup. |
| OUT2SG   | 1    | If 1, a short-to-ground is detected on channel 2 at startup. |
| OUT1SG   | 0    | If 1, a short-to-ground is detected on channel 1 at startup. |

**SHORTED\_LED\_REG (0x19)**

Shorted-LED diagnostics.

|                    |          |          |                    |                    |                    |                    |                    |                    |
|--------------------|----------|----------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|
| <b>BIT</b>         | <b>7</b> | <b>6</b> | <b>5</b>           | <b>4</b>           | <b>3</b>           | <b>2</b>           | <b>1</b>           | <b>0</b>           |
| <b>Field</b>       | –        | –        | OUT6SL             | OUT5SL             | OUT4SL             | OUT3SL             | OUT2SL             | OUT1SL             |
| <b>Reset</b>       | –        | –        | 0b0                | 0b0                | 0b0                | 0b0                | 0b0                | 0b0                |
| <b>Access Type</b> | –        | –        | Read Clears<br>All | Read Clears<br>All | Read Clears<br>All | Read Clears<br>All | Read Clears<br>All | Read Clears<br>All |

| BITFIELD | BITS | DESCRIPTION   |
|----------|------|---|
| OUT6SL   | 5    | If 1, a shorted-LED condition is detected on channel 6. |
| OUT5SL   | 4    | If 1, a shorted-LED condition is detected on channel 5. |
| OUT4SL   | 3    | If 1, a shorted-LED condition is detected on channel 4. |
| OUT3SL   | 2    | If 1, a shorted-LED condition is detected on channel 3. |
| OUT2SL   | 1    | If 1, a shorted-LED condition is detected on channel 2. |
| OUT1SL   | 0    | If 1, a shorted-LED condition is detected on channel 1. |

**MASK1\_REG (0x1A)**

Mask register for the FLTB pin.

| BIT         | 7 | 6 | 5 | 4           | 3           | 2           | 1           | 0           |
|-------------|---|---|---|-------------|-------------|-------------|-------------|-------------|
| Field       | – | – | – | BSTUVMASK   | OMASK       | SGMASK      | OTWMASK     | SLMASK      |
| Reset       | – | – | – | 0b0         | 0b0         | 0b0         | 0b1         | 0b0         |
| Access Type | – | – | – | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read |

| BITFIELD  | BITS | DESCRIPTION  |
|-----------|------|--|
| BSTUVMASK | 4    | When 1, a boost undervoltage fault does not cause the FLTB pin to assert low.  |
| OMASK     | 3    | When 1, an open-LED fault does not cause the FLTB pin to assert low.           |
| SGMASK    | 2    | When 1, a short-to-ground LED fault does not cause the FLTB pin to assert low. |
| OTWMASK   | 1    | When 1, an overtemperature warning does not cause the FLTB pin to assert low.  |
| SLMASK    | 0    | When 1, a shorted-LED fault does not cause the FLTB pin to assert low.         |

**MASK2\_REG (0x1B)**

| BIT         | 7 | 6 | 5           | 4 | 3 | 2 | 1 | 0 |
|-------------|---|---|-------------|---|---|---|---|---|
| Field       | – | – | BATT_UVMASK | – | – | – | – | – |
| Reset       | – | – | 0x0         | – | – | – | – | – |
| Access Type | – | – | Write, Read | – | – | – | – | – |

| BITFIELD    | BITS | DESCRIPTION  |
|-------------|------|--|
| BATT_UVMASK | 5    | When 1, an undervoltage on BATT does not cause FLTB to assert low. |

**DIAG1\_REG (0x1C)**

Boost state, overtemperature-warning/shutdown diagnostics.

| BIT         | 7               | 6         | 5               | 4               | 3               | 2               | 1               | 0               |
|-------------|-----------------|-----------|-----------------|-----------------|-----------------|-----------------|-----------------|-----------------|
| Field       | RTOOR           | ISETOOR   | IREFOOR         | BSTUV           | BSTOV           | HW_RST          | OTW             | OT              |
| Reset       | 0b0             | 0x0       | 0b0             | 0b0             | 0b0             | 0b1             | 0b0             | 0b0             |
| Access Type | Read Clears All | Read Only | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All |

| BITFIELD | BITS | DESCRIPTION   |
|----------|------|---|
| RTOOR    | 7    | This bit is set to 1 if the resistor on the RT pin is out of the expected range. When this happens, the device cannot operate.  |
| ISETOOR  | 6    | When 1, this bit indicates a short to ground on ISET. In this condition, the device does not operate. Power must be recycled to restart the device.                               |
| IREFOOR  | 5    | When 1, this bit indicates that the IREF current is out of range. This is more than likely due to an incorrect resistor value on ISET. In this condition, the IC stops operation. |
| BSTUV    | 4    | If 1, an undervoltage is detected on the boost output, and the boost is disabled.   |
| BSTOV    | 3    | If 1, the boost converter is at its overvoltage limit.  |
| HW_RST   | 2    | If 1, the device has just emerged from a hardware reset (power-up). This bit is reset after the first read from this register.  |
| OTW      | 1    | If 1, the junction temperature of the device is over $T_{WARN}$ , or the temperature foldback circuit has reached the temperature $T1$ .  |
| OT       | 0    | If 1, the junction temperature of the device has exceeded $T_{SHDN}$ or the TEMP input reached the level which shuts off the LED currents.  |

**DIAG2\_REG (0x1D)**

| BIT         | 7               | 6 | 5               | 4 | 3               | 2 | 1 | 0               |
|-------------|-----------------|---|-----------------|---|-----------------|---|---|-----------------|
| Field       | V18OOR          | – | BATT_UV         | – | V5OOR           | – | – | ISNS_SD         |
| Reset       | 0b0             | – | 0b0             | – | 0b0             | – | – | 0b0             |
| Access Type | Read Clears All | – | Read Clears All | – | Read Clears All | – | – | Read Clears All |

| BITFIELD | BITS | DESCRIPTION  |
|----------|------|--|
| V18OOR   | 7    | When 1, this bit indicates that the 1.8V regulator output is not in range.   |
| BATT_UV  | 5    | When 1, this bit indicates that the BATT input is below the $V_{BATT\_LVF}$ level.   |
| V5OOR    | 3    | When 1, this bit indicates that the V5 supply is out of range and that the device was shut down as a consequence.  |
| ISNS_SD  | 0    | When 1, this bit indicates that the voltage between the BATT and SENSE pins exceeded 200mV and the boost converter was disabled unless DIS_ISNS_SD was set to 1. |

**DIM\_TON\_HI (0x29)**

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----|---|---|---|---|---|---|---|---|
|-----|---|---|---|---|---|---|---|---|

|                    |                 |
|--------------------|-----------------|
| <b>Field</b>       | dim_ton_hi[7:0] |
| <b>Reset</b>       | 0x00            |
| <b>Access Type</b> | Read Only       |

| BITFIELD   | BITS | DESCRIPTION   |
|------------|------|---|
| dim_ton_hi | 7:0  | High byte of measured on-time value at DIM pin in units of 50ns. This value is 0 when internal dimming is used. |

**DIM TON MID (0x2A)**

| BIT                | 7                | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|--------------------|------------------|---|---|---|---|---|---|---|
| <b>Field</b>       | dim_ton_mid[7:0] |   |   |   |   |   |   |   |
| <b>Reset</b>       | 0x00             |   |   |   |   |   |   |   |
| <b>Access Type</b> | Read Only        |   |   |   |   |   |   |   |

| BITFIELD    | BITS | DESCRIPTION   |
|-------------|------|---|
| dim_ton_mid | 7:0  | Middle byte of measured on-time value at DIM pin in units of 50ns. This value is 0 when internal dimming is used. |

**DIM TON LO (0x2B)**

| BIT                | 7 | 6 | 5 | 4 | 3 | 2 | 1               | 0 |
|--------------------|---|---|---|---|---|---|-----------------|---|
| <b>Field</b>       | – | – | – | – | – | – | dim_ton_lo[1:0] |   |
| <b>Reset</b>       | – | – | – | – | – | – | 0b00            |   |
| <b>Access Type</b> | – | – | – | – | – | – | Read Only       |   |

| BITFIELD   | BITS | DESCRIPTION  |
|------------|------|--|
| dim_ton_lo | 1:0  | Least-significant bits of measured on-time value at DIM pin in units of 50ns. This value is 0 when internal dimming is used. |

**DIM F HI (0x2C)**

| BIT          | 7             | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|--------------|---------------|---|---|---|---|---|---|---|
| <b>Field</b> | dim_f_hi[7:0] |   |   |   |   |   |   |   |



|                    |           |
|--------------------|-----------|
| <b>Reset</b>       | 0x00      |
| <b>Access Type</b> | Read Only |

| BITFIELD | BITS | DESCRIPTION   |
|----------|------|---|
| dim_f_hi | 7:0  | High byte of measured frequency value at DIM pin in units of 50ns. At 100% and 0% brightness, the frequency read is approximately 80Hz. The value is 0 when internal dimming is used. |

**DIM F MID (0x2D)**

| BIT                | 7              | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|--------------------|----------------|---|---|---|---|---|---|---|
| <b>Field</b>       | dim_f_mid[7:0] |   |   |   |   |   |   |   |
| <b>Reset</b>       | 0x00           |   |   |   |   |   |   |   |
| <b>Access Type</b> | Read Only      |   |   |   |   |   |   |   |

| BITFIELD  | BITS | DESCRIPTION   |
|-----------|------|---|
| dim_f_mid | 7:0  | Middle byte of measured frequency value at DIM pin in units of 50ns. At 100% and 0% brightness, the frequency read is approximately 80Hz. The value is 0 when internal dimming is used. |

**DIM F LO (0x2E)**

| BIT                | 7 | 6 | 5 | 4 | 3 | 2 | 1             | 0 |
|--------------------|---|---|---|---|---|---|---------------|---|
| <b>Field</b>       | – | – | – | – | – | – | dim_f_lo[1:0] |   |
| <b>Reset</b>       | – | – | – | – | – | – | 0b00          |   |
| <b>Access Type</b> | – | – | – | – | – | – | Read Only     |   |

| BITFIELD | BITS | DESCRIPTION  |
|----------|------|--|
| dim_f_lo | 1:0  | Least-significant bits of measured frequency value at DIM pin in units of 50ns. At 100% and 0% brightness, the frequency read is approximately 80Hz. The value is 0 when internal dimming is used. |

## Applications Information

### Power-Circuit Design

First select a converter topology based on whether the total converter output voltage (LED string forward voltage + OUT<sub>+</sub> headroom) is higher than the maximum input voltage, in which case the boost topology can be used. Otherwise, select the SEPIC configuration. Determine the total output current needed to drive the LED strings ( $I_{LED}$ ) using the following equation:

$$I_{LED} = I_{STRING} \times N_{STRING}$$

where  $I_{STRING}$  is the LED current per string in amperes and  $N_{STRING}$  is the number of strings used. Calculate the maximum duty cycle ( $D_{MAX}$ ) using the following equations:

#### Boost Configuration:

$$D_{MAX} = \frac{(V_{LED} + V_{D1} - V_{IN\_MIN})}{(V_{LED} + V_{D1} - V_{DS} - 0.44)}$$

#### SEPIC Configuration:

$$D_{MAX} = \frac{(V_{LED} + V_{D1})}{(V_{IN\_MIN} - V_{DS} - 0.44 + V_{LED} + V_{D1})}$$

where  $V_{D1}$  is the forward drop of the rectifier diode in volts (approximately 0.6V),  $V_{IN\_MIN}$  is the minimum input supply voltage in volts,  $V_{DS}$  is the drain-to-source voltage of the external MOSFET in volts when it is on, and 0.44V is the peak current-sense voltage in the high-current setting. Initially, use an approximate value of 0.2V for  $V_{DS}$  to calculate  $D_{MAX}$ . Calculate a more accurate value of  $D_{MAX}$  after the power MOSFET is selected based on the maximum inductor current.

#### Boost Configuration

The average inductor current varies with the input voltage, and the maximum average current occurs at the lowest input voltage. For the boost converter, the average inductor current is equal to the input current. Select the maximum desired peak-to-peak ripple on the inductor current ( $\Delta I_L$ ). The recommended peak-to-peak ripple is 60% of the average inductor current.

Use the following equations to calculate the maximum average inductor current ( $I_{L\_AVG}$ ) and peak inductor current ( $I_{L\_P}$ ) in amperes.

$$I_{L\_AVG} = \frac{I_{LED}}{1 - D_{MAX}}$$

Allowing the peak-to-peak inductor ripple  $\Delta I_L$  to be  $\pm 30\%$  of the average inductor current:

$$\Delta I_L = I_{L\_AVG} \times 0.3 \times 2$$

and

$$I_{L\_P} = I_{L\_AVG} + \frac{\Delta I_L}{2}$$

Calculate the minimum inductance value ( $L_{MIN}$ ), in henries with the inductor-current ripple set to the maximum value.

$$L_{MIN} = \frac{(V_{IN\_MIN} - V_{DS} - 0.44) \times D_{MAX}}{f_{SW} \times \Delta I_L}$$

where 0.44V is the peak current-sense voltage (with  $bl\_ilim$  set to 0; if  $bl\_ilim$  is set to 1, use 0.325V in this equation). Choose an inductor that has a minimum inductance greater than the calculated  $L_{MIN}$  and a current rating greater than  $I_{L\_P}$ . The recommended saturation current limit of the selected inductor is 10% higher than the inductor peak current for the boost configuration.

#### SEPIC Configuration

Power-circuit design for the SEPIC configuration is very similar to a boost design. For SEPIC, the output is referenced to ground and the inductor is split into two parts (see the [Typical Application Circuit](#)). One of the inductors ( $L_2$ ) has the LED

current as the average current, and the other inductor (L1) has the input current as its average current. Use the following equations to calculate the average inductor currents ( $IL1_{AVG}$ ,  $IL2_{AVG}$ ) and peak inductor currents ( $IL1_P$ ,  $IL2_P$ ) in amperes:

$$IL1_{AVG} = \frac{I_{LED} \times D_{MAX} \times 1.1}{1 - D_{MAX}}$$

The factor 1.1 provides a 10% margin to account for the converter losses:

$$IL2_{AVG} = I_{LED}$$

Assuming the peak-to-peak inductor ripple  $\Delta I_L$  is  $\pm 30\%$  of the average inductor current:

$$\Delta I_{L1} = IL1_{AVG} \times 0.3 \times 2$$

and

$$IL1_P = IL1_{AVG} + \frac{\Delta I_{L1}}{2}$$

$$\Delta I_{L2} = IL2_{AVG} \times 0.3 \times 2$$

and

$$IL2_P = IL2_{AVG} + \frac{\Delta I_{L2}}{2}$$

Calculate the minimum inductance values  $L1_{MIN}$  and  $L2_{MIN}$  in henries with the inductor current ripples set to the maximum value as follows:

$$L1_{MIN} = \frac{(V_{IN\_MIN} - V_{DS} - 0.44) \times D_{MAX}}{f_{SW} \times \Delta I_{L1}}$$

$$L2_{MIN} = \frac{(V_{IN\_MIN} - V_{DS} - 0.44) \times D_{MAX}}{f_{SW} \times \Delta I_{L2}}$$

where 0.44V is the peak current-sense voltage. Choose inductors that have a minimum inductance greater than the calculated  $L1_{MIN}$  and  $L2_{MIN}$ , and current ratings greater than  $IL1_P$  and  $IL2_P$ , respectively. The recommended saturation current limit of the selected inductor is 10% higher than the inductor peak current.

To simplify further calculations, consider L1 and L2 as a single inductor with L1/L2 connected in parallel. The combined inductance value and current is calculated as follows:

$$L_{MIN} = \frac{L1_{MIN} \times L2_{MIN}}{L1_{MIN} + L2_{MIN}}$$

and

$$IL_{AVG} = IL1_{AVG} + IL2_{AVG}$$

where  $IL_{AVG}$  represents the total average current through both the inductors connected together for SEPIC configuration. Use these values in the calculations for the SEPIC configuration in the following sections. Select coupling capacitor CS so that its peak-to-peak ripple is less than 2% of the minimum input supply voltage. This ensures that the second-order effects created by the series resonant circuit comprising L1, CS, and L2 do not affect the operation of the converter. Use the following equation to calculate the minimum value of CS:

$$CS \geq \frac{I_{LED} \times D_{MAX}}{V_{IN\_MIN} \times 0.02 \times f_{SW}}$$

where CS is the minimum value of the coupling capacitor in farads,  $I_{LED}$  is the LED current in amperes, and the factor 0.02 reflects the desired 2% ripple.

### Current-Sense Resistor and Slope Compensation

The MAX25560 backlight controller generates a current ramp for slope compensation. This ramp current is synchronized to the switching frequency, starting from zero at the beginning of every clock cycle and rising linearly to reach 50 $\mu$ A at the end of the clock cycle. The slope-compensating resistor ( $R_{SC}$ ) is connected between the CSP input and the source of the external MOSFET. This adds a programmable ramp voltage to the CSP input voltage to provide slope compensation.

Use the following equations to calculate the value of slope-compensation resistance ( $R_{SC}$ ):

**Boost Configuration:**

$$R_{SC} = \frac{(V_{LED} - 2 \times V_{IN\_MIN}) \times R_{CS} \times 3}{L_{MIN} \times 50\mu A \times f_{SW} \times 4}$$

**SEPIC and Coupled-Inductor Configurations:**

$$R_{SC} = \frac{(V_{LED} - V_{IN\_MIN}) \times R_{CS} \times 3}{L_{MIN} \times 50\mu A \times f_{SW} \times 4}$$

where  $V_{LED}$  and  $V_{IN\_MIN}$  are in volts,  $R_{SC}$  and  $R_{CS}$  are in ohms,  $L_{MIN}$  is in henries, and  $f_{SW}$  is in hertz. The value of the switch current-sense resistor ( $R_{CS}$ ) can be calculated as follows:

**Boost Configuration:**

$$R_{CS} = \frac{4 \times L_{MIN} \times f_{SW} \times V_{CS\_MAX} \times 0.9}{I_{LP} \times 4 \times L_{MIN} \times f_{SW} + D_{MAX} \times (V_{LED} - 2 \times V_{IN\_MIN}) \times 3}$$

**SEPIC and Coupled-Inductor Configurations:**

$$R_{CS} = \frac{4 \times L_{MIN} \times f_{SW} \times V_{CS\_MAX} \times 0.9}{I_{LP} \times 4 \times L_{MIN} \times f_{SW} + D_{MAX} \times (V_{LED} - V_{IN\_MIN}) \times 3}$$

where  $V_{CS\_MAX}$  is the minimum value of the peak current-sense threshold or 0.38V with  $bl\_ilim = 0$  and 0.275V when  $bl\_ilim$  is set to 1. The current-sense threshold also includes the slope-compensation component. The minimum current-sense threshold is multiplied by 0.9 to take tolerances into account.

**Output Capacitor Selection**

In both converter topologies, the output capacitor supplies the load current when the main switch is on. The function of the output capacitor is to reduce the converter output ripple to acceptable levels. The entire output-voltage ripple appears across the constant-current sink outputs because the LED string voltages are stable due to their constant current. For the MAX25560, limit the peak-to-peak output-voltage ripple to 250mV in order to get stable output current.

The ESR, ESL, and bulk capacitance of the output capacitor contribute to the output ripple. In most applications, using low-ESR ceramic capacitors can dramatically reduce the output ESR and ESL effects, connecting multiple ceramic capacitors in parallel to achieve the required bulk capacitance. To minimize audible noise during PWM dimming however, it may be desirable to limit the use of ceramic capacitors on the boost output. In such cases, an additional electrolytic or tantalum capacitor can provide the majority of the bulk capacitance.

**External Switching MOSFET Selection**

The external switching MOSFET should have a voltage rating sufficient to withstand the maximum boost output voltage together with the rectifier diode drop and any possible overshoot due to ringing caused by parasitic inductance and capacitance. The recommended MOSFET  $V_{DS}$  voltage rating is 30% higher than the sum of the maximum output voltage and the rectifier diode drop.

The continuous drain-current rating of the MOSFET ( $I_D$ ), when the case temperature is at the maximum operating ambient temperature, should be greater than that calculated in the following equation:

$$I_{DRMS} = \left( \sqrt{I_{LAVG}^2 \times D_{MAX}} \right) \times 1.3$$

The MOSFET dissipates power due to both switching losses and conduction losses. Use the following equation to calculate the conduction losses in the MOSFET.

$$P_{COND} = I_{LAVG}^2 \times D_{MAX} \times R_{DS(ON)}$$

where  $R_{DS(ON)}$  is the on-state, drain-to-source resistance of the MOSFET. Use the following equation to calculate the switching losses in the MOSFET:

$$P_{SW} = \frac{I_{LAVG} \times V_{LED}^2 \times C_{GD} \times f_{SW}}{2} \times \left( \frac{1}{I_{GON}} + \frac{1}{I_{GOFF}} \right)$$

where  $I_{GON}$  and  $I_{GOFF}$  are the gate currents of the MOSFET in amperes when it is turned on and turned off, respectively.  $C_{GD}$  is the gate-to-drain MOSFET capacitance in farads.

### Rectifier Diode Selection

Using a Schottky rectifier diode produces less forward drop and puts the least burden on the MOSFET during reverse recovery. A diode with considerable reverse-recovery time increases the MOSFET switching loss. Select a diode with a voltage rating that is 20% higher than the maximum boost-converter output voltage and a current rating greater than:

$$I_D = I_{LAVG} \times (1 - D_{MAX}) \times 1.2$$

### Feedback Compensation

During normal operation, the feedback control loop regulates the minimum  $OUT_{-}$  voltage to fall within the window comparator limits of 0.78V and 1.03V when LED string currents are enabled during PWM dimming. When LED currents are off during PWM dimming, the control loop turns off the converter and stores the previous boost output-voltage value for use during the next on cycle. The switching converter small-signal-transfer function has a right-half plane (RHP) zero in the boost configuration if the inductor current is in continuous-conduction mode. The RHP zero adds a 20dB/decade gain together with a 90° phase lag, which is difficult to compensate.

#### Worst-Case RHP Zero Frequency ( $f_{ZRHP}$ ):

$$f_{ZRHP} = V_{LED} \times \frac{(1 - D_{MAX})^2}{2 \times \pi \times L \times I_{LED}}$$

#### SEPIC and Coupled-Inductor Configurations:

$$f_{ZRHP} = V_{LED} \times \frac{(1 - D_{MAX})^2}{2 \times \pi \times L \times I_{LED} \times D_{MAX}}$$

The standard way to avoid this zero is to roll off the loop gain to 0dB at a frequency of less than 1/5 of the RHP zero frequency with a -20dB/decade slope. The switching converter small-signal transfer function also has an output pole. The effective output impedance, together with the output filter capacitance, determines the output pole frequency ( $f_{P1}$ ) that is calculated as follows:

#### Boost Configuration:

$$f_{P1} = \frac{I_{LED}}{\pi \times V_{LED} \times C_{OUT}}$$

#### SEPIC and Coupled-Inductor Configurations:

$$f_{P1} = I_{LED} \times \frac{D_{MAX}}{\pi \times V_{LED} \times C_{OUT}}$$

Compensation components  $R_{COMP}$  and  $C_{COMP}$  perform two functions.  $C_{COMP}$  introduces a low-frequency pole that presents a -20dB/decade slope to the loop gain.  $R_{COMP}$  flattens the gain of the error amplifier for frequencies above the zero formed by  $R_{COMP}$  and  $C_{COMP}$ . For compensation, this zero is placed at  $f_{P1}$  to provide a -20dB/decade slope for frequencies above  $f_{P1}$  to the combined modulator and compensator response. The value of  $R_{COMP}$  needed to fix the total loop gain at  $f_{P1}$  so the total loop gain crosses 0dB with -20dB/decade slope at 1/5 the RHP zero frequency is calculated as follows:

#### Boost Configuration:

$$R_{COMP} = f_{ZRHP} \times R_{CS} \times I_{LED} \times A_{OVP} / (5 \times f_{P1} \times G_{MCOMP} \times V_{LED} \times (1 - D_{MAX}))$$

#### SEPIC and Coupled-Inductor Buck-Boost Configurations:

$$R_{COMP} = f_{ZRHP} \times R_{CS} \times I_{LED} \times A_{OVP} \times D_{MAX} / (5 \times f_{P1} \times G_{MCOMP} \times V_{LED} \times (1 - D_{MAX}))$$

where:

$R_{COMP}$  = Compensation resistor in  $\Omega$

$A_{OVP}$  = BSTMON resistor-divider gain (a value  $\gg 1$ )

$R_{CS}$  = Current-sense resistor in  $\Omega$

$GM_{COMP}$  = Transconductance of the error amplifier (600 $\mu$ S)

The value of  $C_{COMP}$  is calculated as follows:

$$C_{COMP} = \frac{1}{2 \times \pi \times f_{Z1} \times R_{COMP}}$$

where  $f_{Z1}$  is the compensation zero placed at 1/5 the crossover frequency, which is, in turn, set at 1/5 the  $f_{ZRHP}$ .

If the output capacitors do not have low ESR, the ESR zero frequency could fall below the 0dB crossover frequency. An additional pole may be required to cancel out this zero placed at the same frequency. This can be added by connecting a capacitor from the COMP pin directly to GND with a value shown as follows:

$$C_{PAR} = GM_{COMP} \times R_{ESR} \times C_{OUT}$$

where  $R_{ESR}$  is the capacitor ESR value and  $C_{OUT}$  is the output-capacitor value.

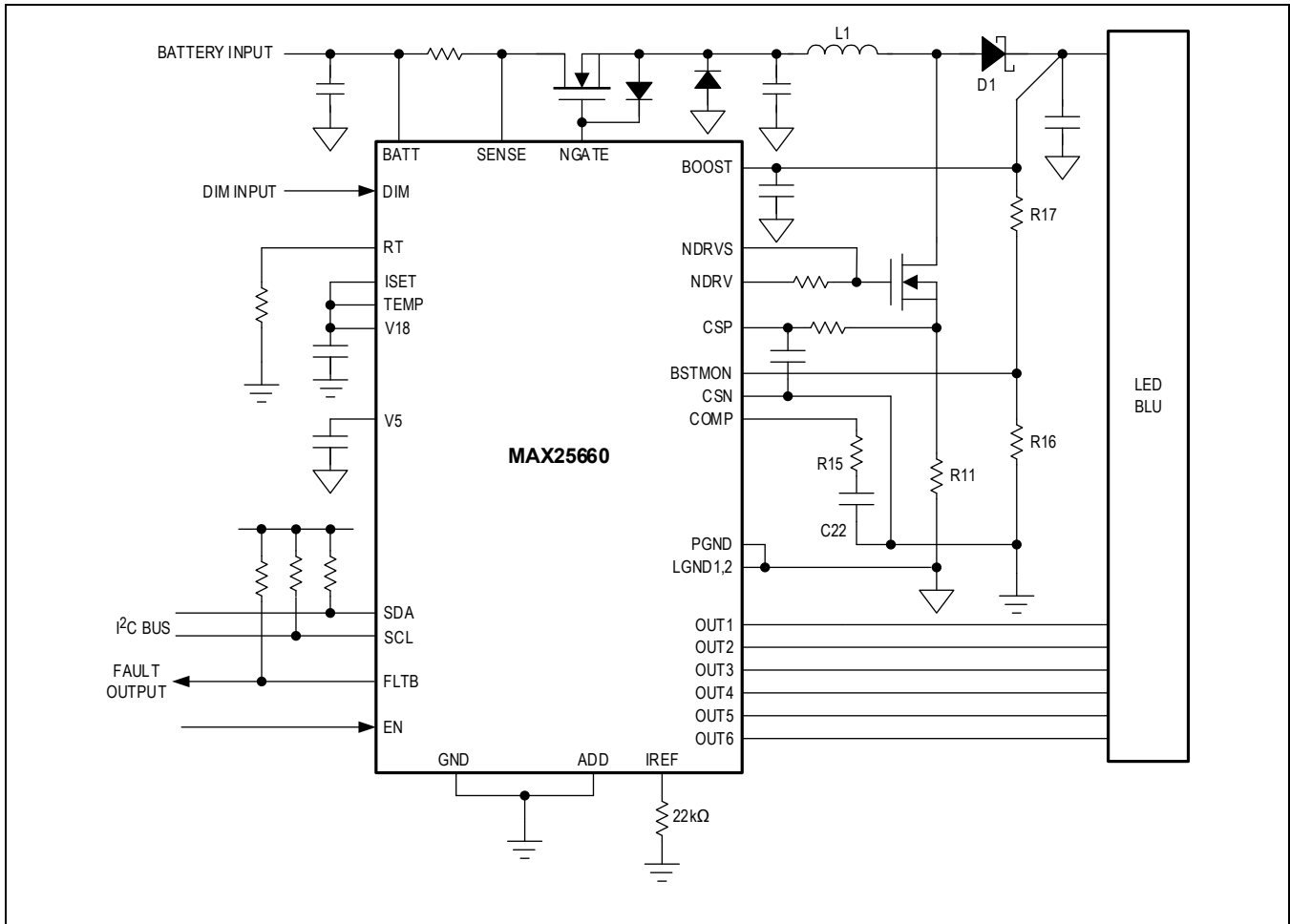
### PCB Layout Considerations

The MAX25560 incorporates a high-frequency switching converter and, as such, careful circuit board layout is required to ensure correct device operation and optimize EMI performance. The switching-converter portion of the circuit contains nodes with very fast voltage transients, which could lead to undesirable effects on the sensitive parts of the circuit. Observe the following guidelines when designing a circuit board for the MAX25560:

1. Make the connections from the sense resistor to the BATT and SENSE pins as short and as wide as possible. This ensures a low-resistance connection, which enhances sensing accuracy.
2. Connect the components related to the following pins as close as possible to the device to avoid noise pickup: ISET, RT, BSTMON, and COMP. Connect their ground terminals to an analog ground plane or directly to the device GND pin. The CSN pin should be connected directly to the ground of the network connected to COMP.
3. Connect the bypass capacitors on V18 as close as possible to the device, and connect the capacitor ground to the nearest GND pin. Connect the GND of the device to the analog ground plane using a via placed close to GND.
4. Connect the bypass capacitors on V5 as close as possible to the device, and connect the capacitor ground to power GND.
5. Have a power-ground plane for the switching-converter power circuit under the power components (i.e., input filter capacitor, output filter capacitor, inductor, MOSFET, rectifier diode, and current-sense resistor). Connect PGND to the power-ground plane closest to PGND. Connect all other ground connections to the power ground plane using vias placed close to the terminals.
6. There are two loops in the power circuit that carry high-frequency switching currents. One loop is when the MOSFET is on (from the input filter capacitor positive terminal, through the inductor, the internal MOSFET, and the current-sense resistor, to the input capacitor negative terminal). The other loop is when the MOSFET is off (from the input capacitor positive terminal, through the inductor, the rectifier diode, and the output filter capacitor, to the input capacitor negative terminal). Analyze these two loops and make the loop areas as small as possible. Wherever possible, have a return path on the power-ground plane for the switching currents on the top-layer copper traces, or through power components. This reduces the loop area considerably and provides a low-inductance path for the switching currents. Reducing the loop area also reduces radiation during switching.
7. Connect the power-ground plane for the constant-current LED-driver portion of the circuit to LEDGND as close as possible to the device. Connect GND to PGND at the same point.
8. Boost output voltage for the LED strings should be taken directly from the output capacitors and not from the boost diode anode.
9. Input and output capacitors need good grounding with wide traces and multiple vias to the ground plane.

Typical Application Circuit

Boost Configuration



Ordering Information

| PART           | TEMP RANGE      | PACKAGE CODE | PIN-PACKAGE |
|----------------|-----------------|--------------|-------------|
| MAX25560ATJ/V+ | -40°C to +125°C | T3255+6C     | 32-TQFN-EP* |

/V Denotes an automotive-qualified part.

+ Denotes a lead(Pb)-free/RoHS-compliant package.

\*EP = Exposed pad.

T Denotes tape-and-reel.

Chip Information

PROCESS: BiCMOS

## Revision History

| REVISION NUMBER | REVISION DATE | DESCRIPTION  | PAGES CHANGED |
|-----------------|---------------|--|---------------|
| 0               | 1/24          | Initial release  | —             |
| 1               | 3/24          | Corrected dimming ratio in Benefits and Features; updated Ordering Information table | 1, 47         |

